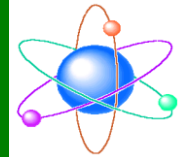


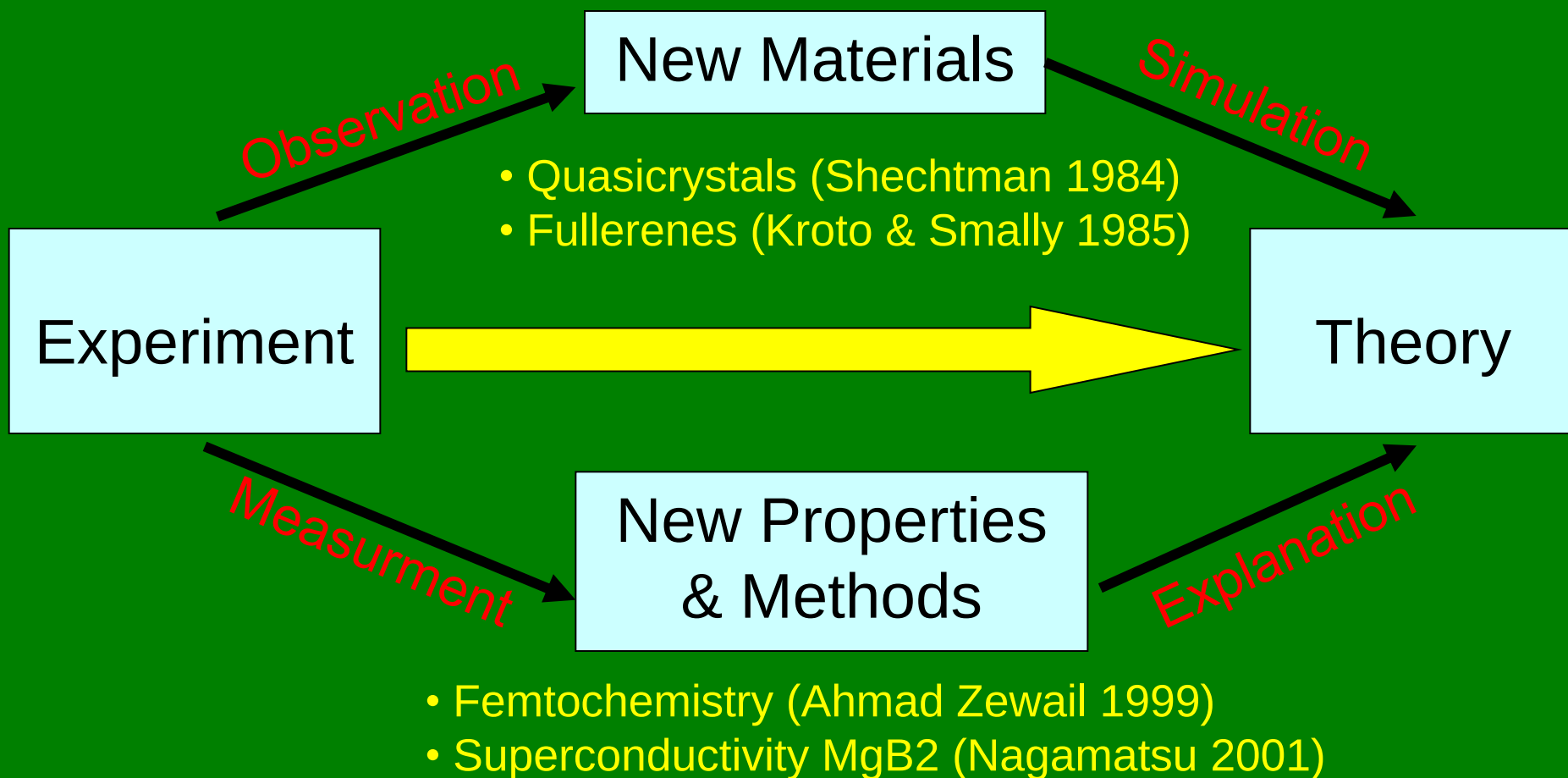
Towards Novel Boron Nanostructured Materials: Theoretical Predictions and Experimental Confirmations.

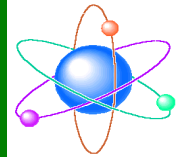


Technische Universität Dresden
Chair Material Science and Nanotechnology
April 30, 2009

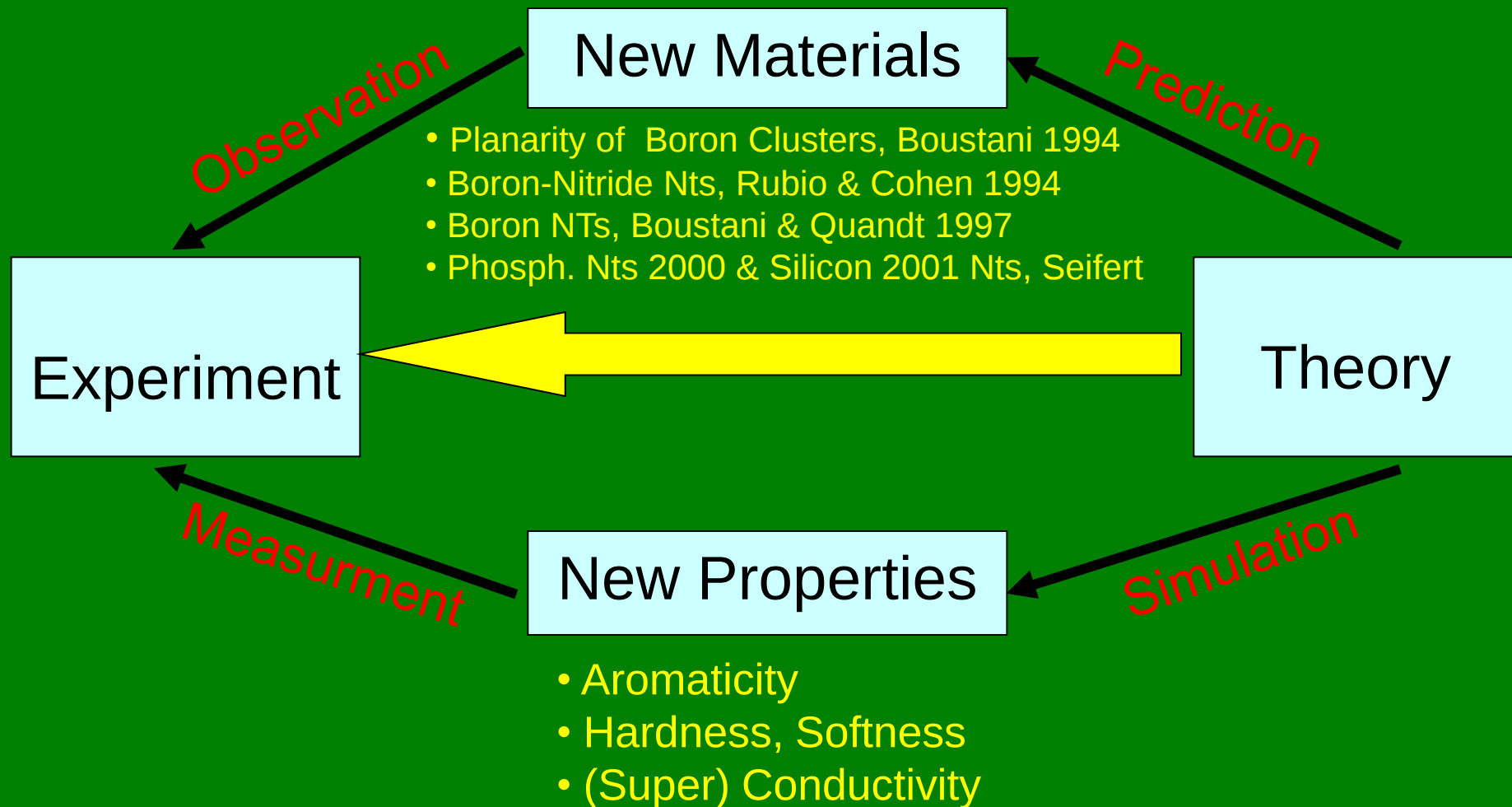


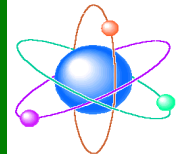
Conventional Approach





Opposite Approach





Survey of the Talk

• Outlines

- Why Boron
- Solid Boron
- Boron Clusters

• Theoretical Methods

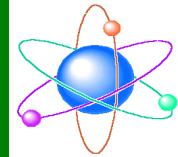
- Basic Concepts
- Ab Initio Methods
- Geometry Optimization

• Novel Boron

- Clusters & Cages
- Sheets & Nanotubes
- Nanoribbons

• Applications

- Nanotechnology
- Space Industry
- Medicine



Motivations

- Mass Spectra of Boron Clusters:

Geometrical Structures

Electronic Properties

- Search for New Materials with definite properties:

Superlight

Superhardness

High Temperature

Anti-Corrosion

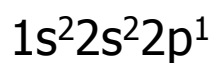
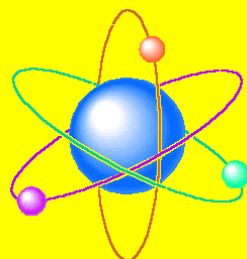
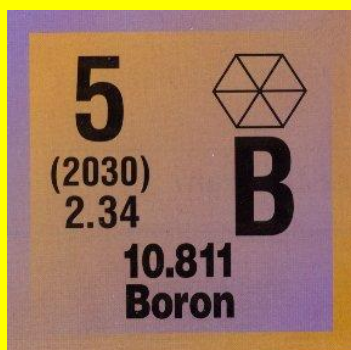
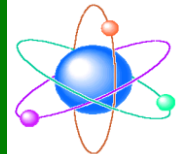
Manufacturable

(Semi) Conductive

- Computationally Applicable

Lightweight Atoms

at Nanoscale Sizes

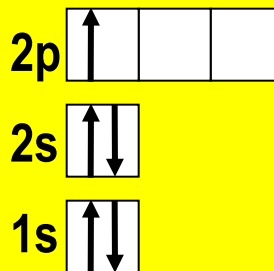


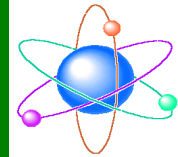
Special properties

- High melting point
- Thermal conductive
- Semi-, Superconductor
- Hardness close to Diamond

Atomic properties

- Electron deficient
- Short covalent radius
- More Orbitals than Valence Electrons



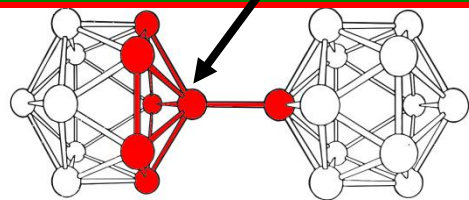


Crystalline Rhombohedral α -Boron

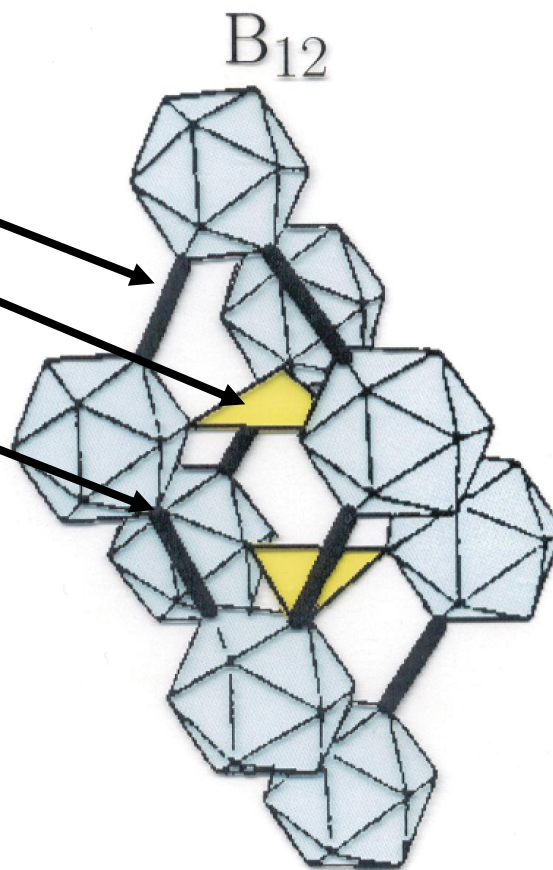
2-center bonds

3-center bonds

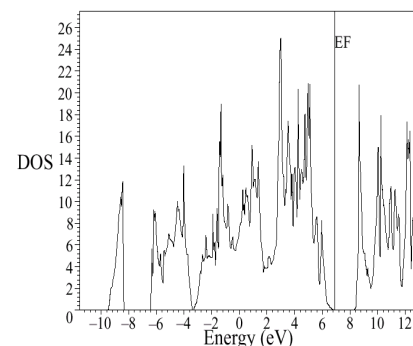
multi-center bonds

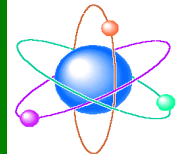


Inverse umbrella
bonding (along edges of
unit cell)



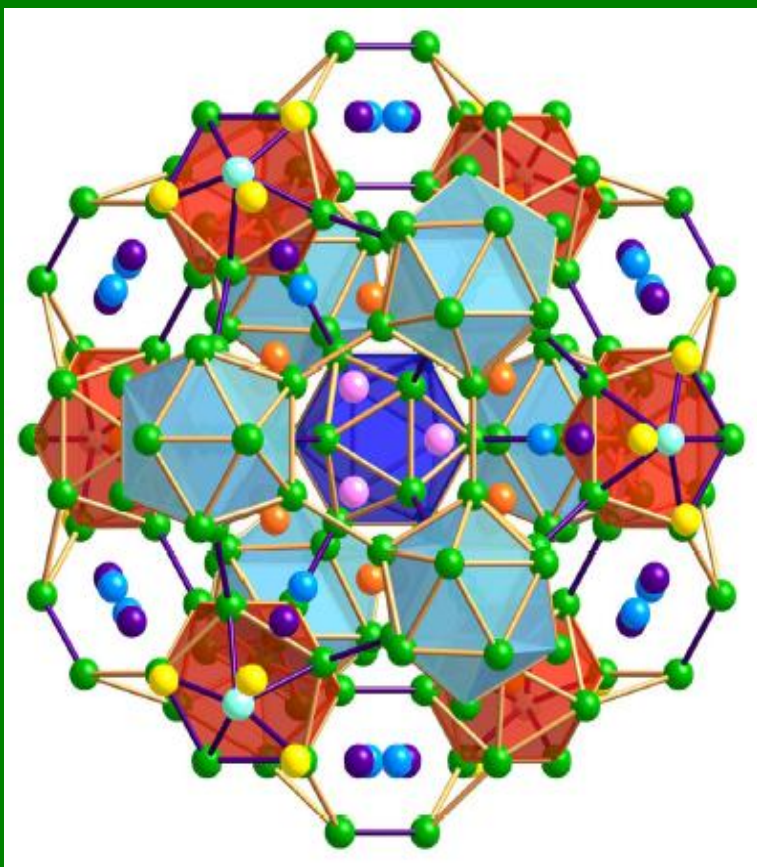
Density of States:
Semiconductor with
Bandgap of 1.57 eV





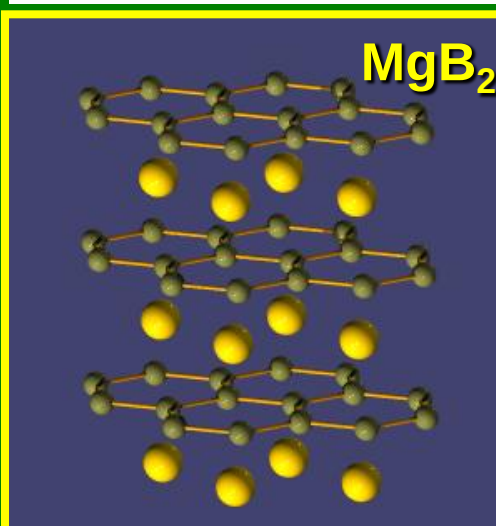
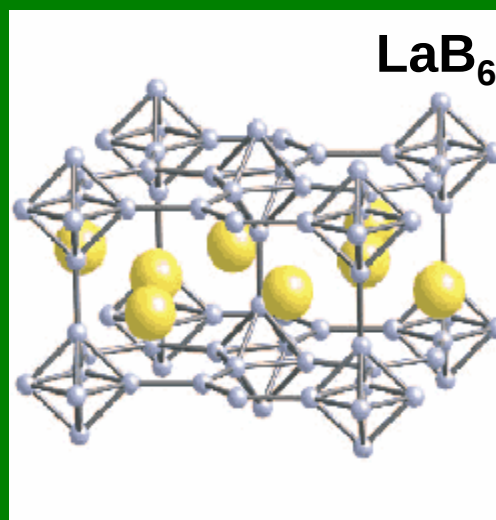
Crystalline β -Boron

Widom et al., PRB 77, 064113 (2008)

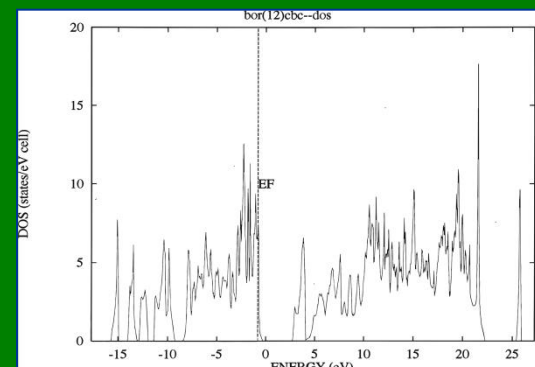
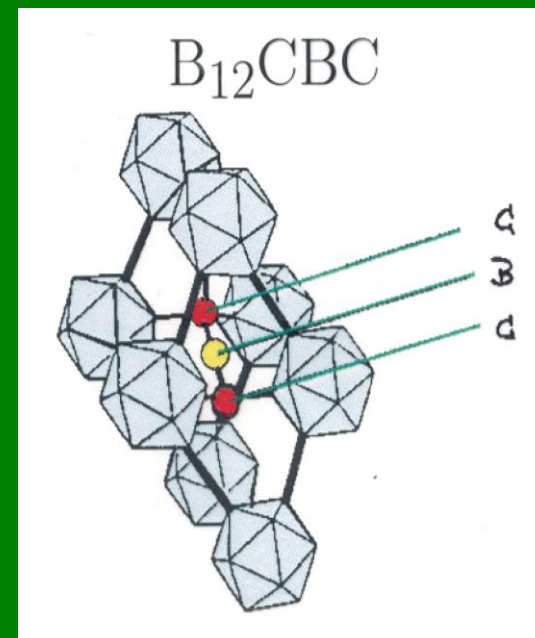


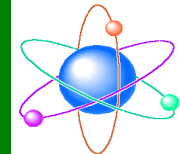
β -Boron viewed along the
rhombohedral 111 axis

Metal-Hexaborides & Diborides



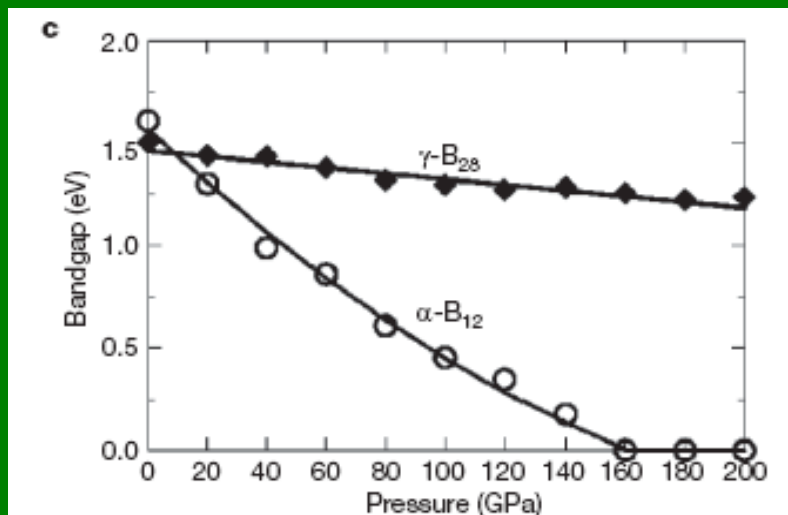
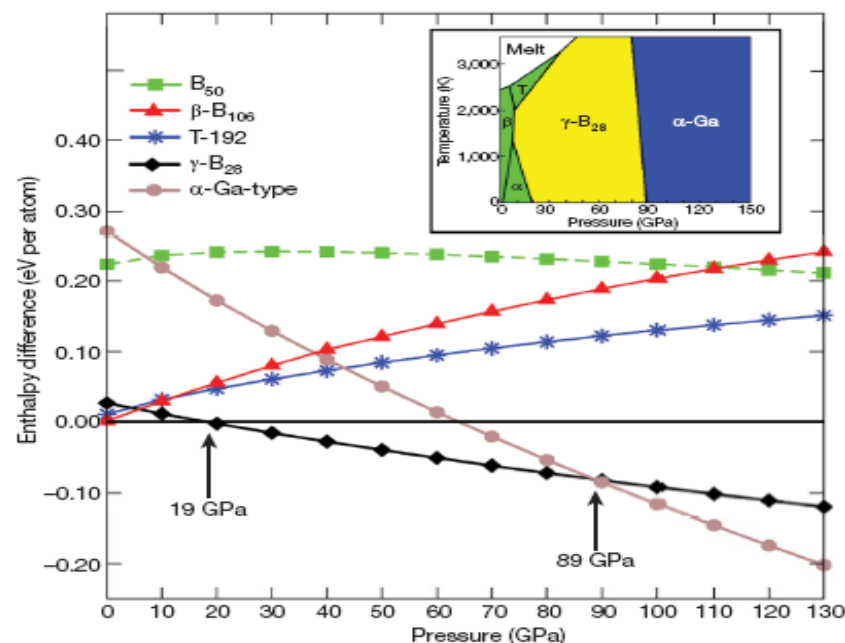
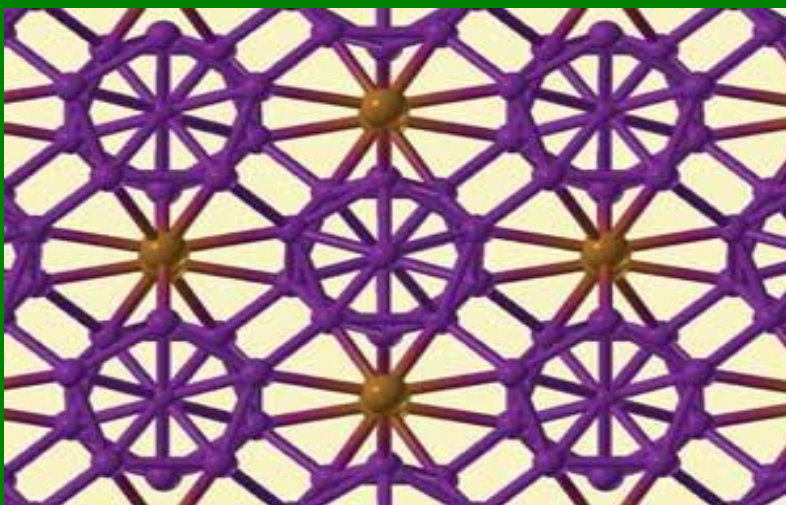
Doped α -Boron, Bylander & Kleinman PRB 43, 1487 (1991)



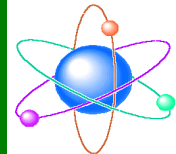


Novel Crystal: γ - Boron

A R Oganov et al, *Nature*, 2009, DOI:10.1038/nature07736



At 19 GPa α -B₁₂ transforms to γ -B₂₈
At 89 GPa γ -B₂₈ transforms to α -Ga
 γ -B₂₈ is at 200 GPa an insulator with
a bandgap of 1.25 eV



Mass Spectra of Boron Clusters

Hanley, Whitten and Anderson JPC 92, 8503, 1988

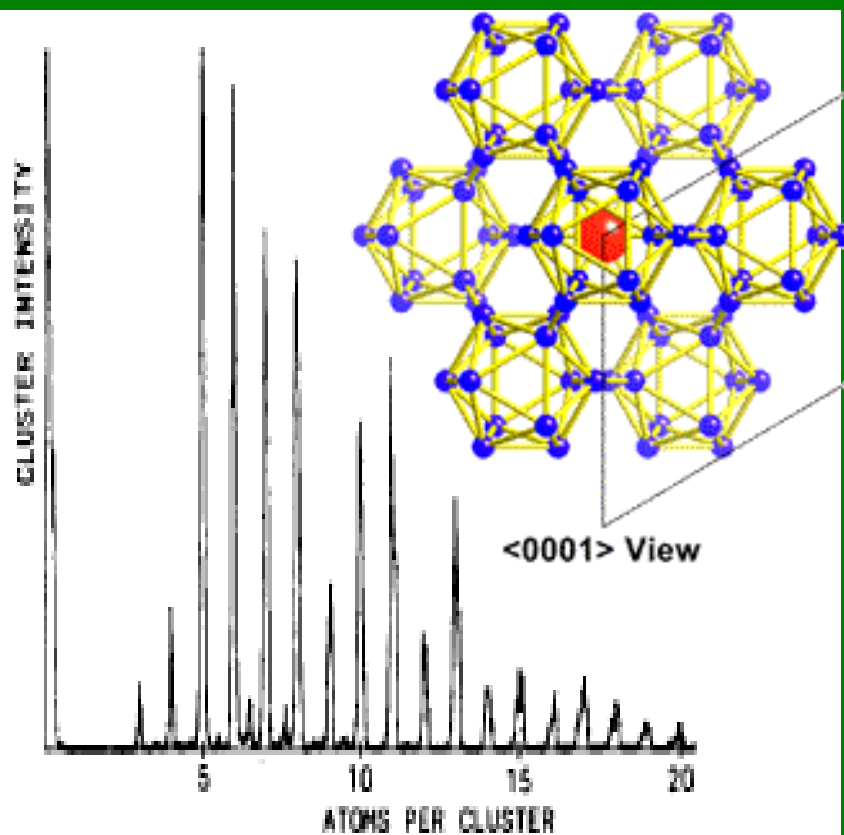
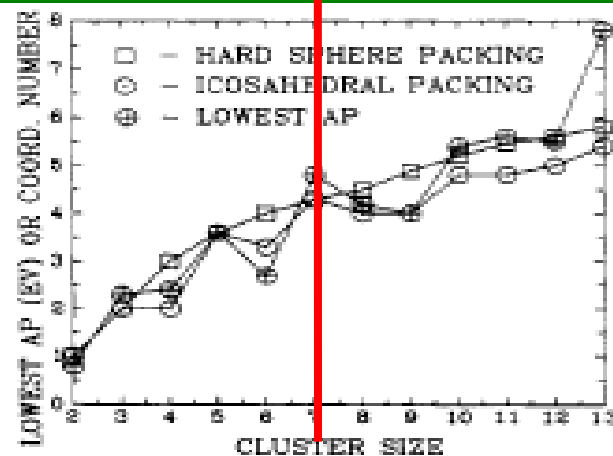
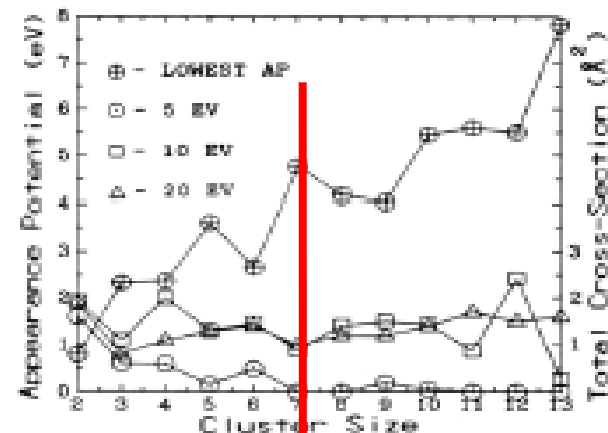
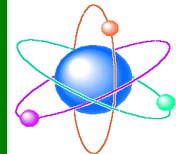


Figure 2. Typical mass distribution of B_n^+ from the laser ablation source.

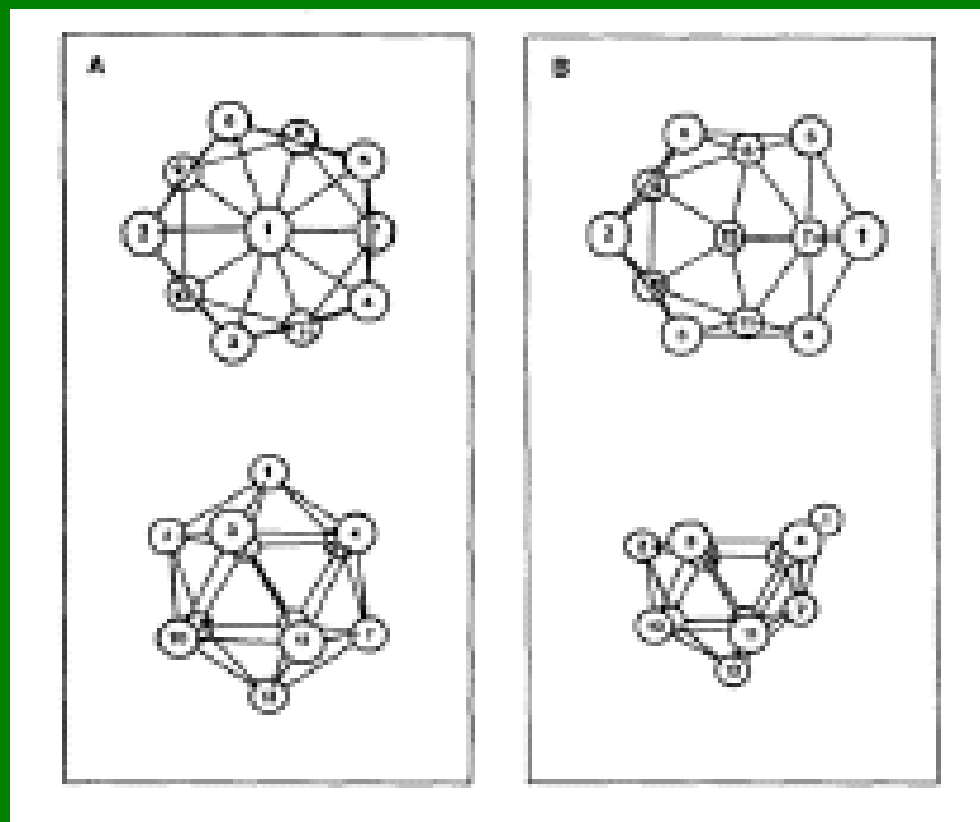
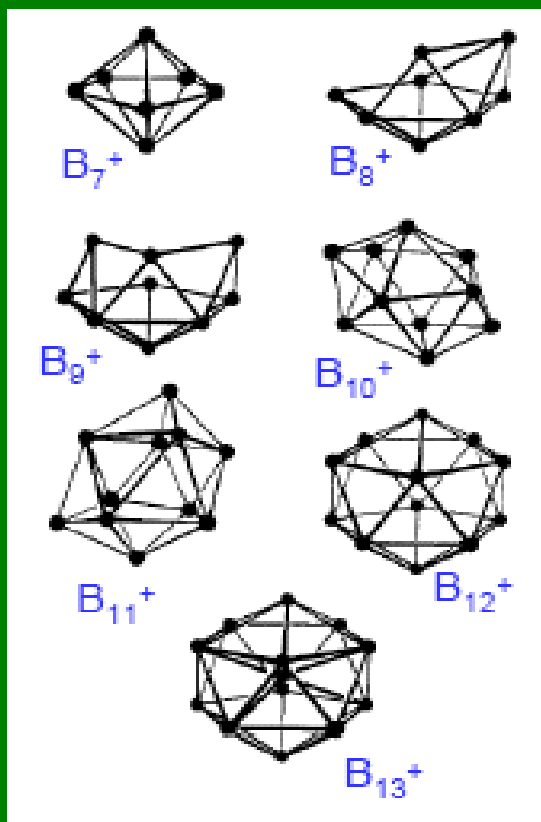


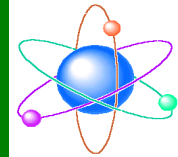


3D Boron Clusters

Anderson et al., *J. Phys. Chem.* 91, 5161, (1987)
and 92, 5803 (1988)

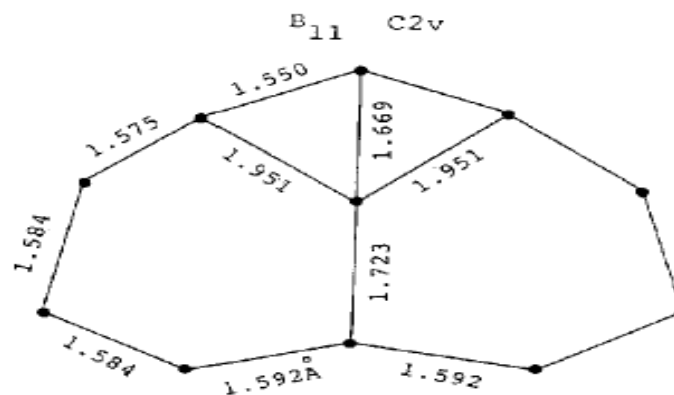
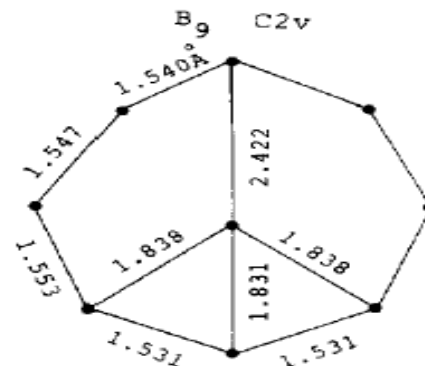
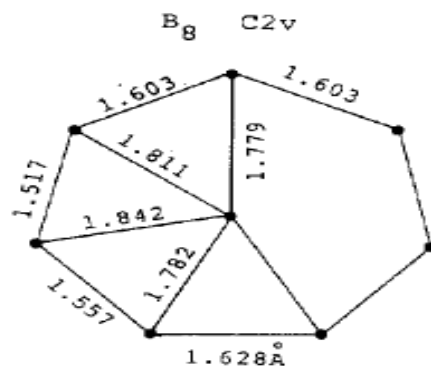
Kawai & Weare, *J. Chem. Phys.*, 95, 1151 (1991)

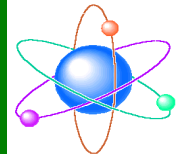




2D Boron Clusters

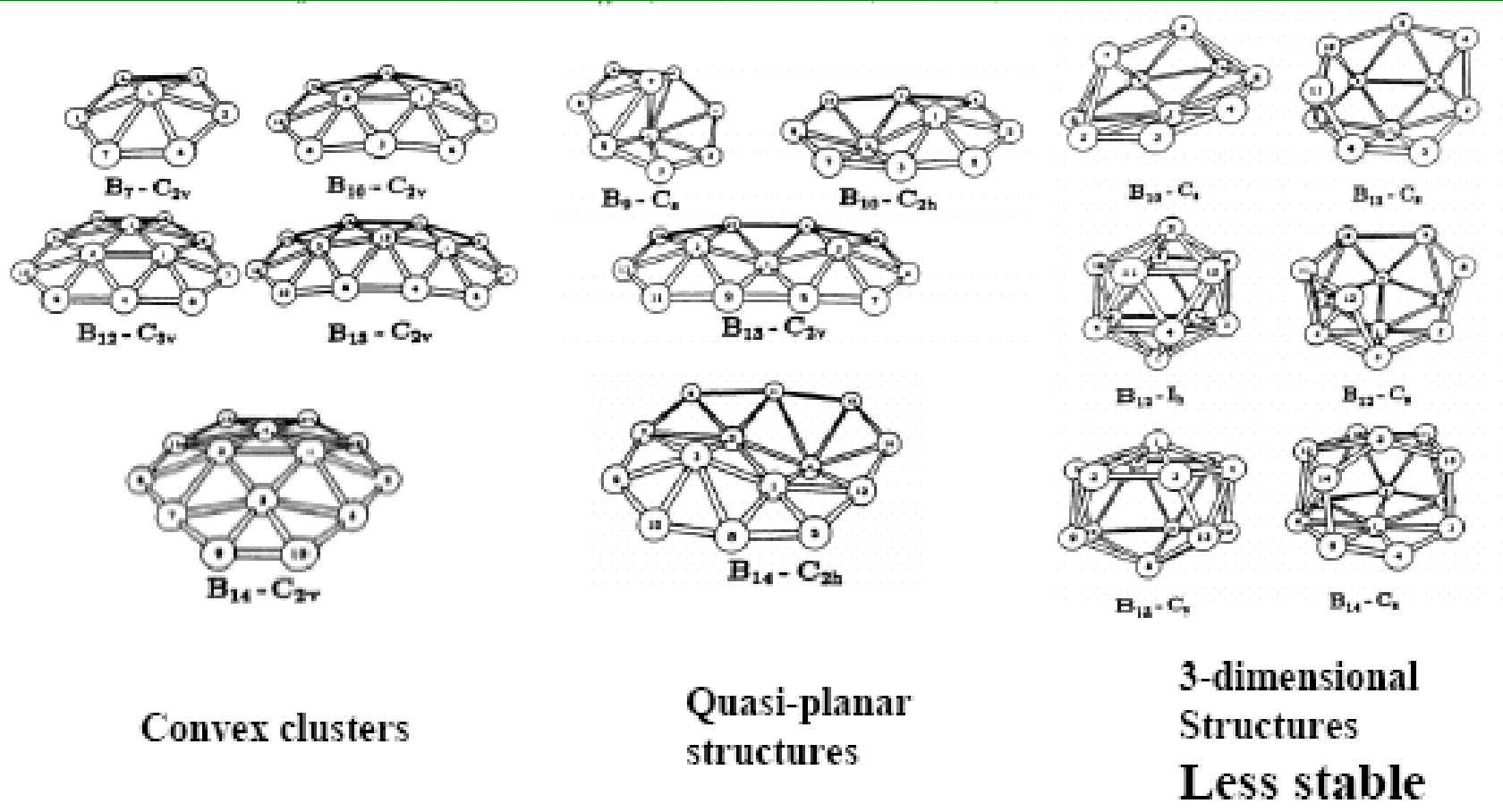
Kato & Yamashita, *Chem. Phys. Lett.* 190, 362 (1992)

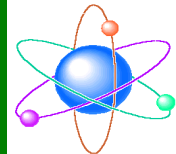




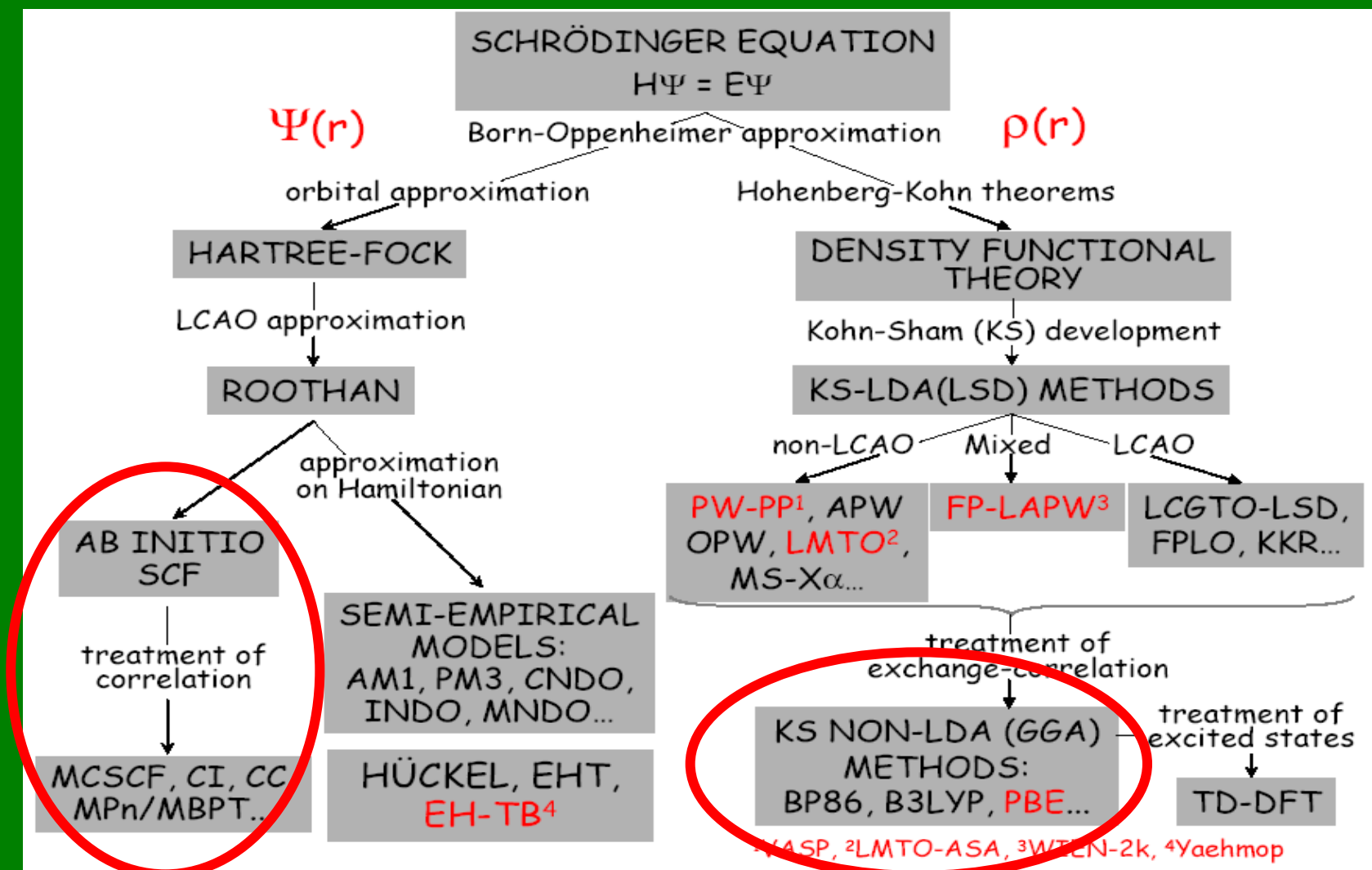
Prediction of Quasi-planar Boron Clusters

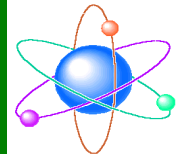
Boustani, IJQC 52, 1081 (1994)





Theoretical Methods





Novel Boron

CitationIndex 2008 Ihsan Boustani

215	PRB	35, 9437, 1987
37	IJQC	52,1081,1994
11	CPL	214, 381 ,1995
48	CPL	240, 135 ,1995
35	CPL	233, 273, 1995

Clusters ,Sheets & Nanotubes

Ricca	Chem. Phys.	208 233, 1996
Gu	J. Comp. Chem.	19, 203, 1997
Fowler	JPC A	104, 397, 2000
Cao	JP. Cond. M.	13, 5065, 2000
Shvartsburg	JPCA	104, 9448, 2000

Nanowires & Belts Ribbons & Rings

Wu,	Adv. Mater.	13,1487, 2001
Cao,	Adv. Mater.	13, 1701, 2001
Ruoff,	JACS	124, 4564, 2001
Wang,	CPL	367, 495, 2002
Rühle	APL	80,4228, 2002

PRL, Nature, JACS, Nano Letters, PRB ...

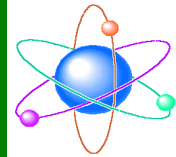
23	CMS	11, 132, 1998
34	CPL	311, 21 , 1999
62	JCP	110, 3176, 1999
10	IJQC	78,131, 2000
15	JCP	113, 3814 ,2000
17	JSSC	154,269, 2000
7	CPL	339, 362, 2001
22	PRB	64, 125422, 2001

Wang etal	APL	83,5280,2003
Lipscomb	InorgCh	37, 6544, 1998
Ciuparu etal	JPCB	108,3967, 2004
Evans etal	PRB	72,45434, 2005
Cabria etal	Nanotech.	17, 778, 2006
Kunstmann	PRB	74, 35416, 2006
Guo etal	Nanotech.	1,58237,2006
Lau etal	PRB	xx,xxx, 2006

Wang,	CPL	368, 663, 2003
Wu,	Microelec. J.	34, 463,2003
Meng,	CPL	370, 825, 2003
Yang,	CPL	379, 87, 2003
Wang,	Ap. Phys. A	79,891,2004
Xu,	Nano Lett.	4, 963, 2004
Ahlrichs	Angew Chem I	46 2007
Tang Ismail	PRL	99, 115501 2007

Over 1000 papers

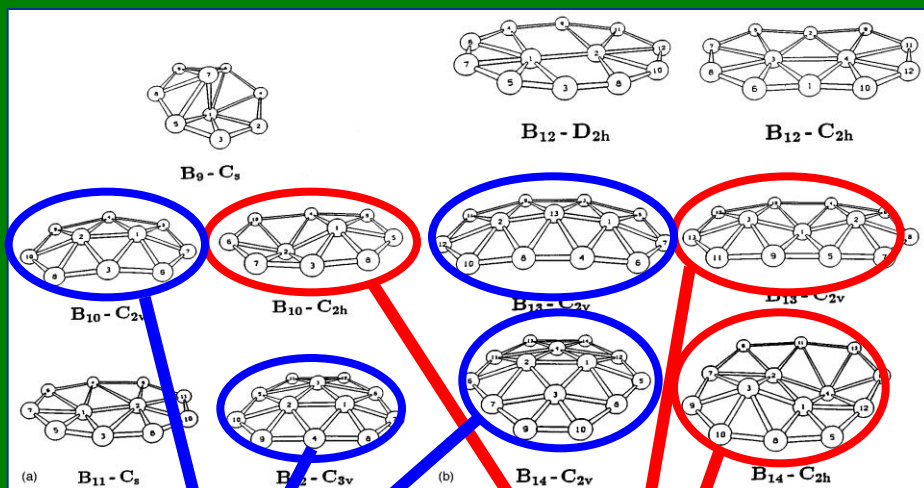
Hirsch-Index 20



Prediction of Quasi-planar Boron Clusters

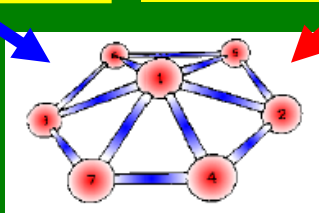
Boustani, IJQC 52, 1081 (1994)

2D Clusters



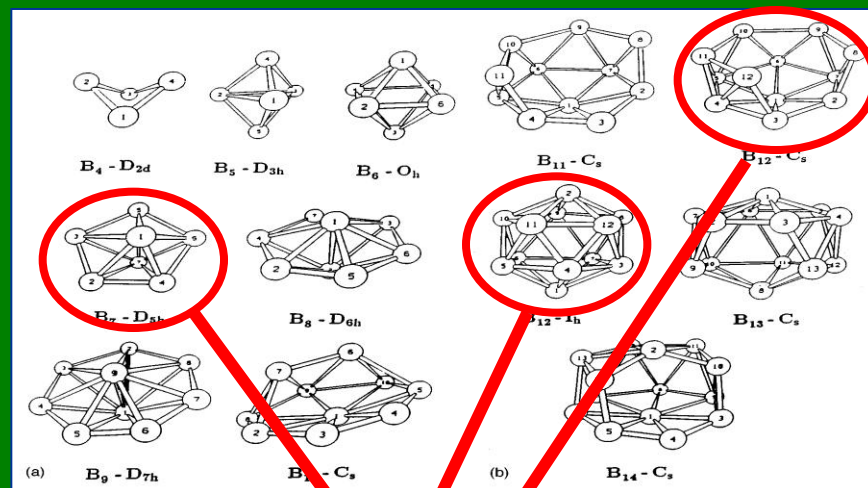
Convex

Quasiplanar

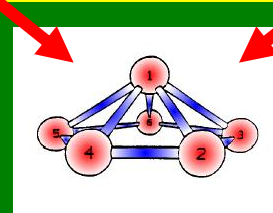


Hexagonal Pyramide

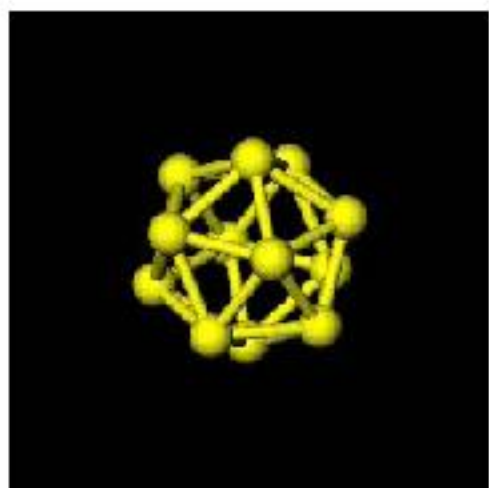
3D Clusters

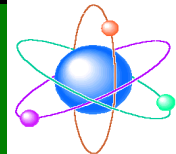


(Open) Spheres



Pentagonal Pyramide

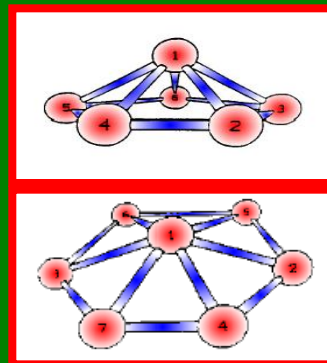




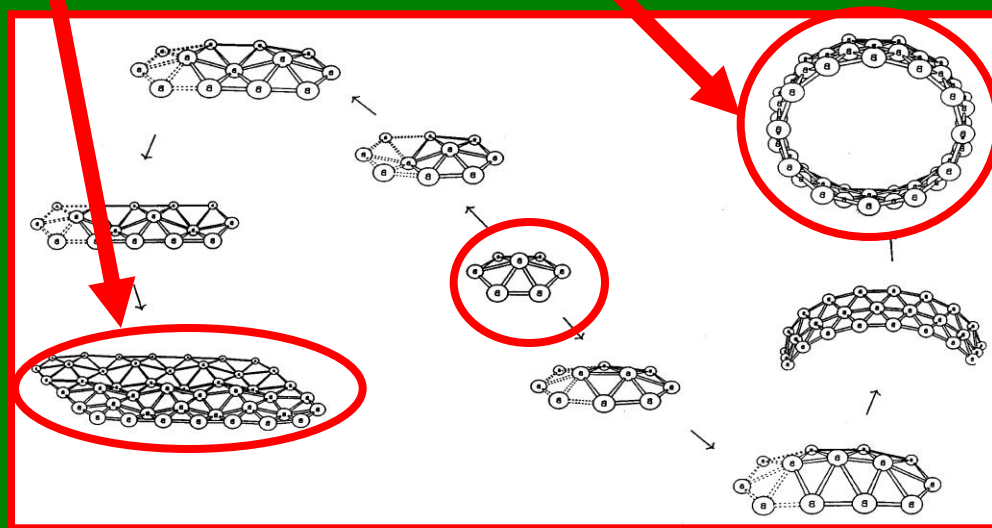
The Aufbau Principle

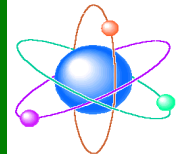
Boustani, CPL 240, 135 (1995), PRB 55, 16426 (1997)

Highly stable Boron Clusters and Spheres
can be constructed from *two* basic units :
 B_6 & B_7 , while Boron Sheets & Nanotubes
only from *one* basic units : B_7



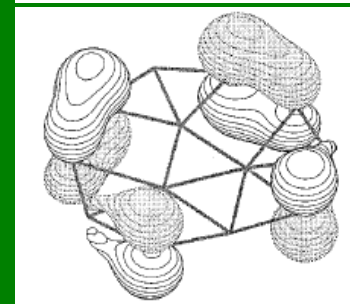
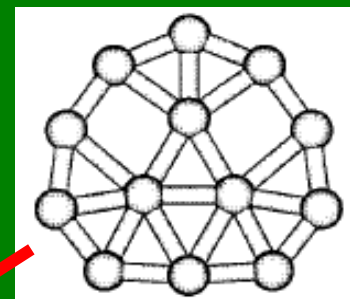
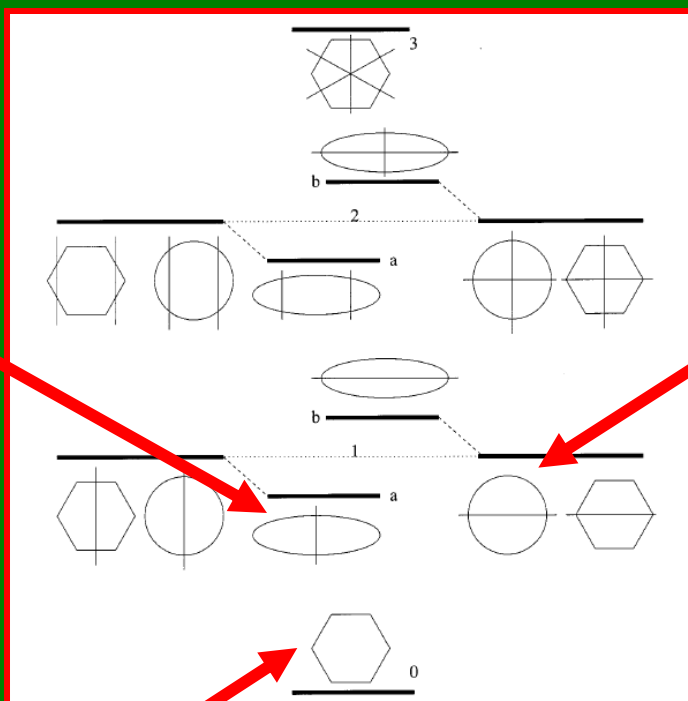
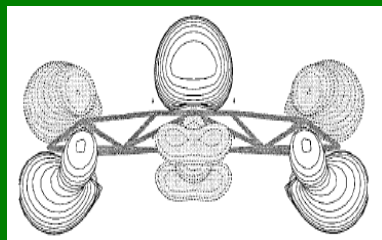
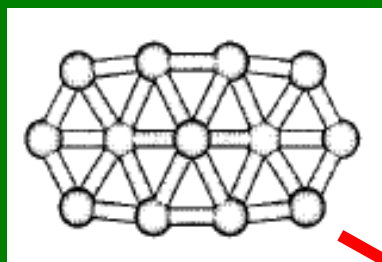
The Aufbau starts by
consecutively adding
atoms to B_7 forming
new hexagonal
pyramids *generating*
Sheets or Nanotubes.



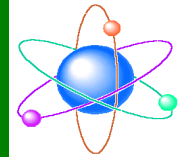


Theoretical Confirmation I Curiously Stable Quasipolar B_{13}^+

Fowler & Ugalde, JPC A 104, 394 (2000)



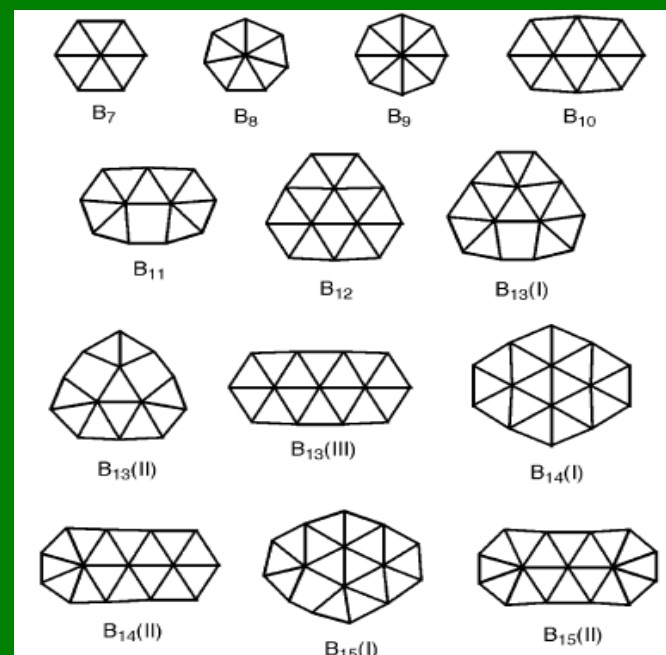
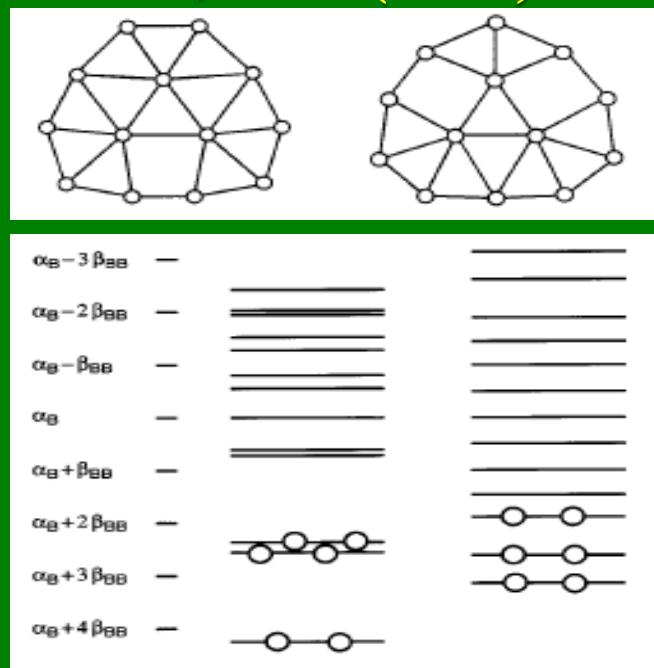
Similar to Benzene, Cationic B_{13} is Aromatic



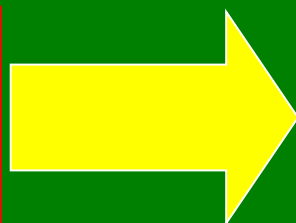
Theoretical Confirmation II of Quasipolar Clusters

J. Aihara, JPCA
105, 5486 (2001)

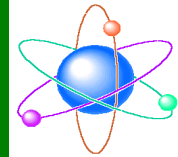
J. Aihara, JACS
127, 13324 (2005)



π -MOs with six
 π electrons

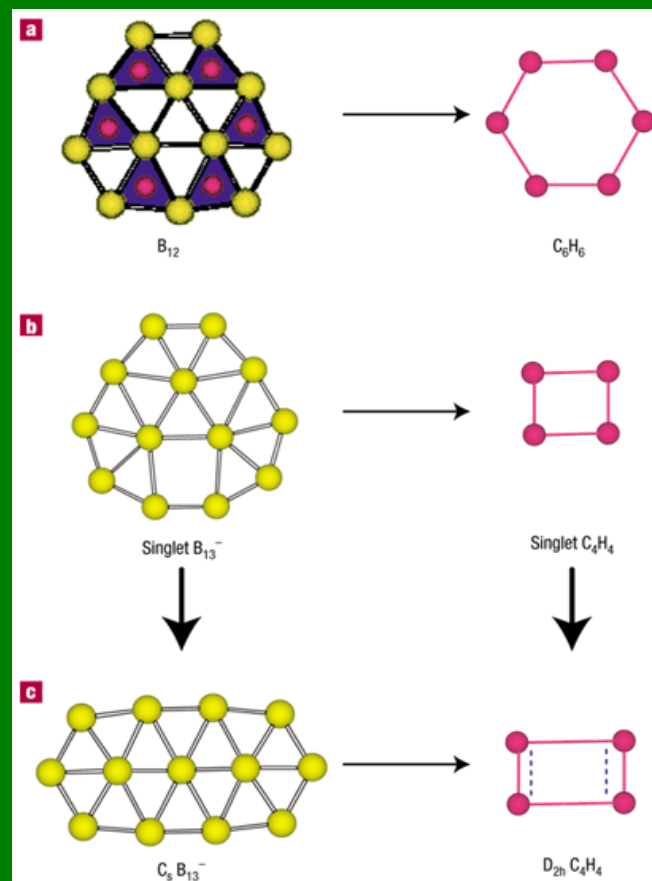
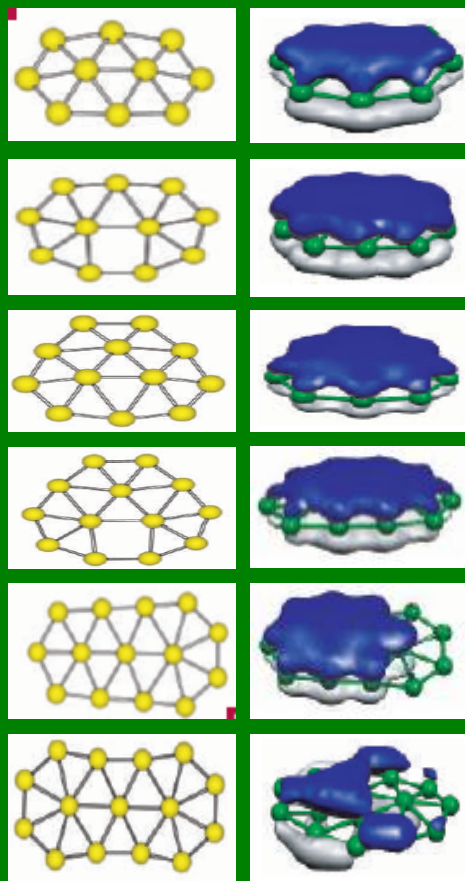
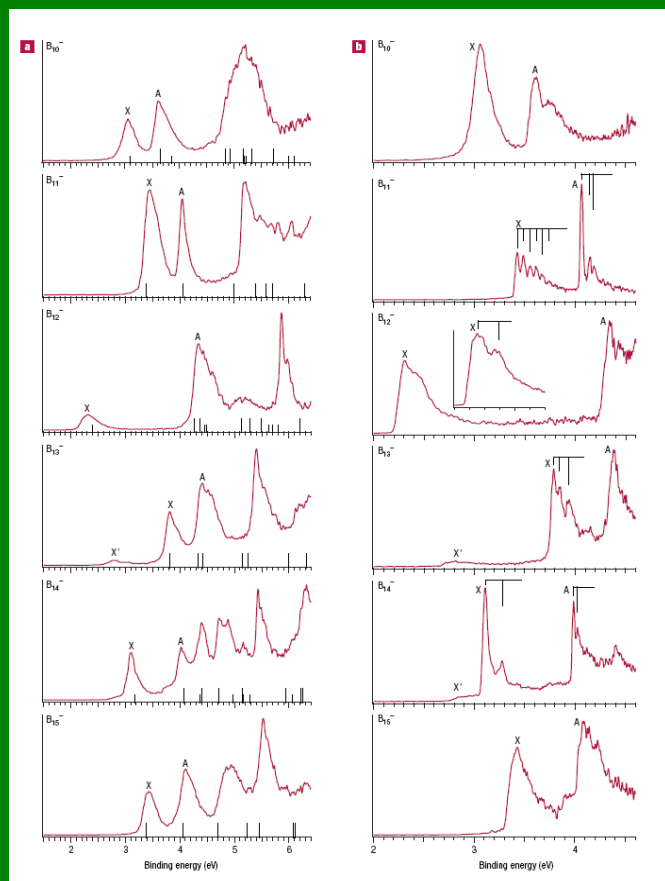


Aromaticity of Planar
Clusters is confirmed



Experimental Confirmation of Quasiplanarity I

LS Wang et al. Nature Mat. 2, 827 (2003)

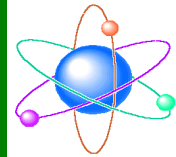


Vertical Electron Detachment

B_n Clusters

π -MOs

Aromatic Boron Clusters



Experimental Confirmation of Quasiplanarity II

Oger et al., Angew. Chem. Int. Ed. 46, 8503–8506 (2007)

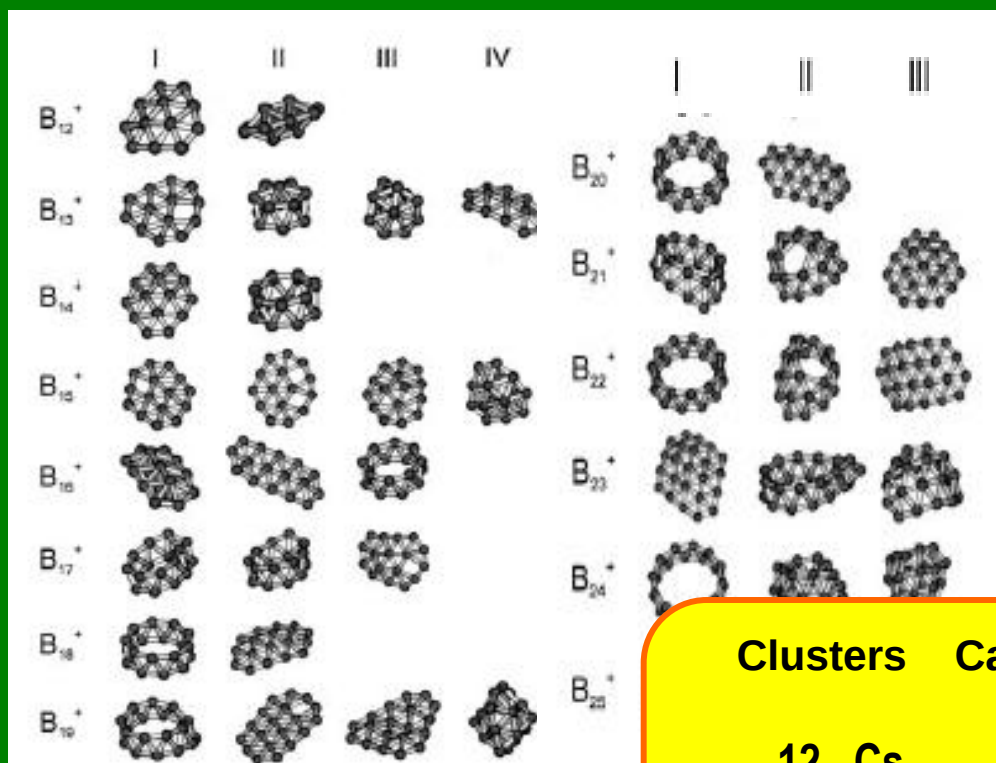
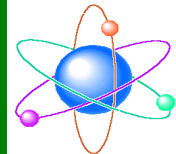


Table 2: Comparison of experimental and calculated cross sections.^[a]

Cluster size	Number	Symmetry/ state label	ΔE [eV]	Ω_{calcd} [Å ²]	Ω_{expd} [Å ²]
12	I	$C_{2v}/^2A''$	0	62.8*	63.6 ± 1.9
	II	$D_{2h}/^2A_u$	0.48	58.6	
13	I	C_{2v}	0	66.7*	66.7 ± 0.9
	II	C_{3v}	0.84	58.7	
	III	C_{3v}	0.89	59.5	
	IV	C_s	1.04	66.9	
22	I	$C_{2h}/^2B_u$	0	89.1	83.2 ± 1.4
	II	$C_{1v}/^2A$	0.08	81.7*	
	III	$C_{2v}/^2A$	1.13	90.2	
23	I		0	91.4	84.9 ± 1.8
			0.48	90.7	
			0.89	84.6*	
				95.9*	
				80.0	94.9 ± 2.9
				80.7	

Collision Cross
Sections

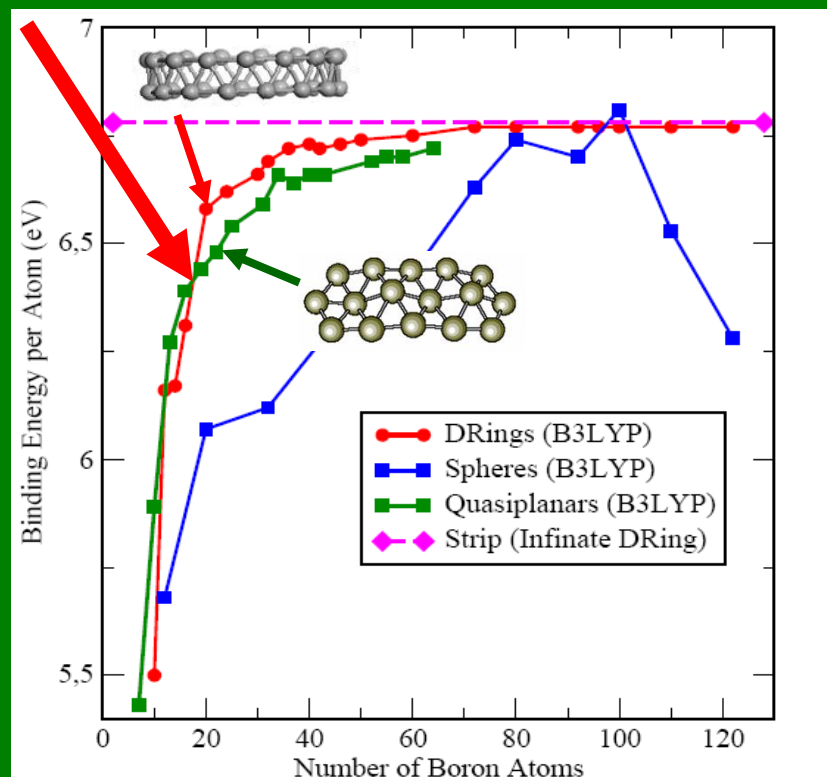
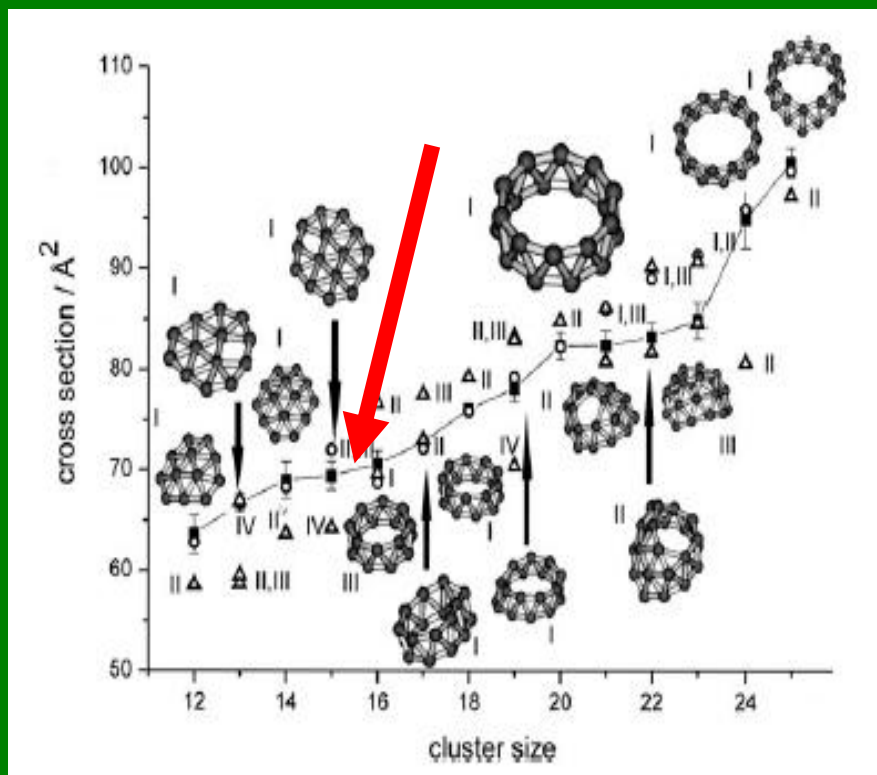
Clusters	Calculated	Collision Cross Sections
12 Cs	62.8	63.6 ± 1.9
13 C2v	66.7	66.7 ± 0.9
14 C2v	68.3	69.0 ± 1.8
15 Cs	72.1	69.4 ± 2.6



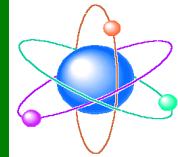
Transition from Quasiplanar to Cylindrical Structure

Oger et al., Angew. Chem. Int. Ed.
46, 8503 –8506 (2007)

Pandey & Boustani
J. Phys., submitted (2008)



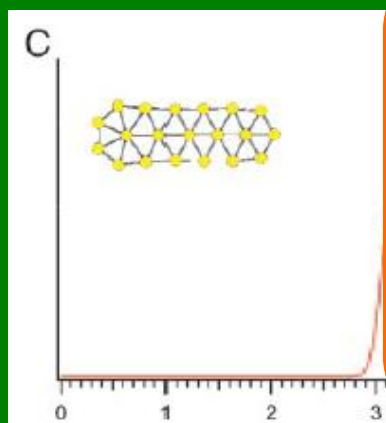
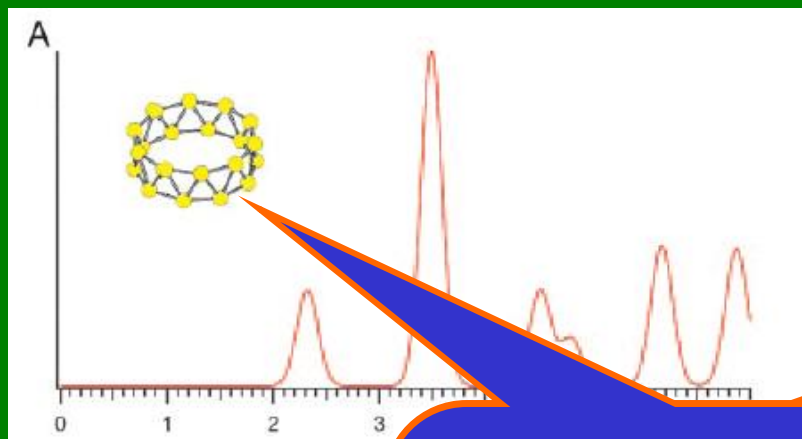
Transition between Quasi-Planar and Cylindrical Structures at B₁₆



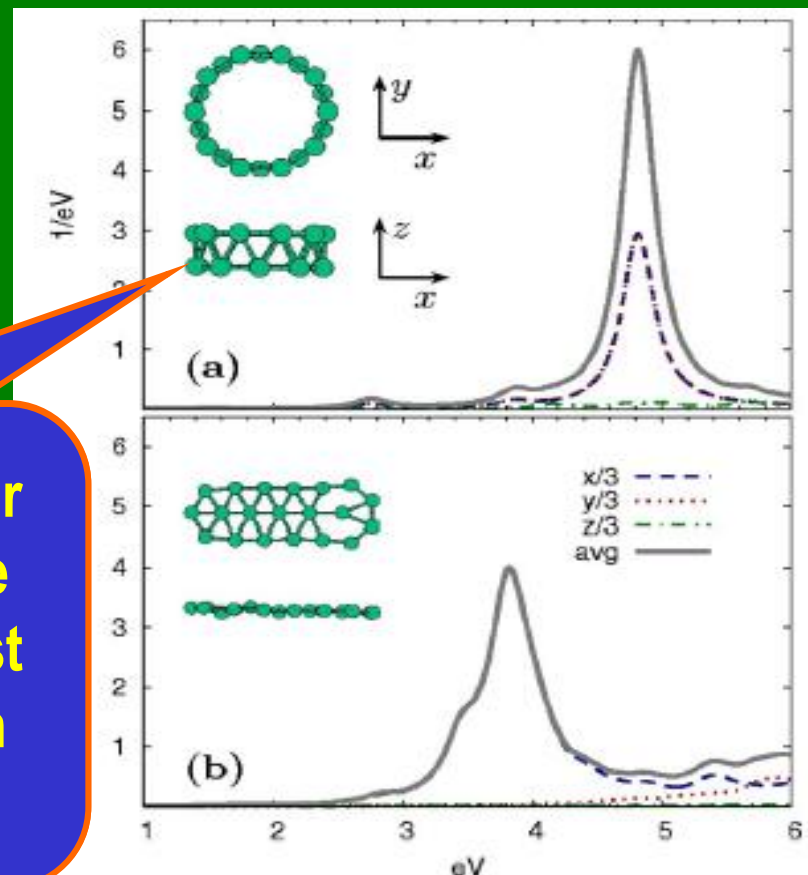
Transition from Quasiplanar to Cylindrical Structure II

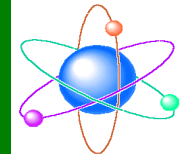
B_{20} as the embryo of SWBNTs
Kiran et al., PNAS 102, 964 (2005)

Structural Transition via Optical Absorption
Marques & Botti, JCP 123, 014310 (2005)



The tubular B_{20} cluster
may be viewed as the
embryo of the thinnest
boron nanotube, with
a diameter of 5.2 Å.





On the Strong Ring Currents in B20 and neighboring Boron Toroids

M. P. Johansson, J. Phys. Chem. C 113, 524 (2009)

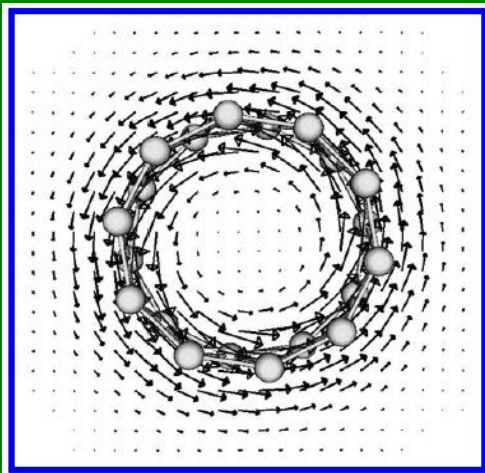
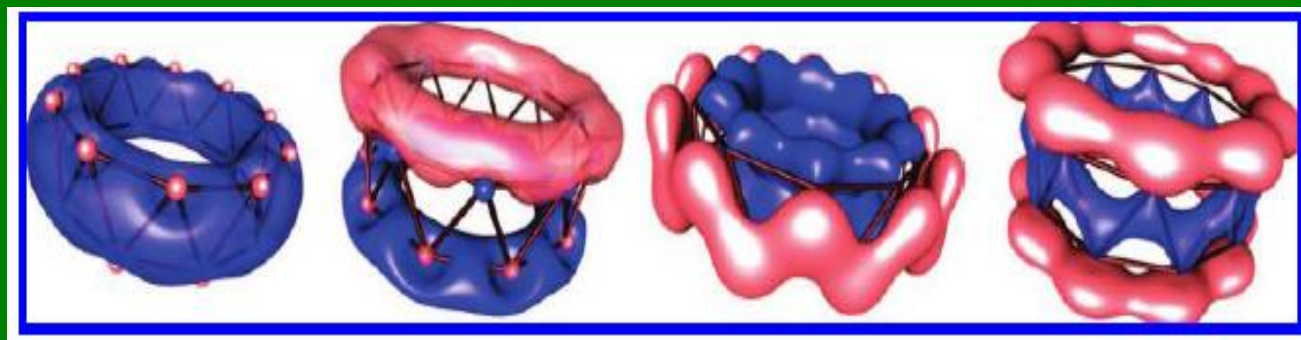
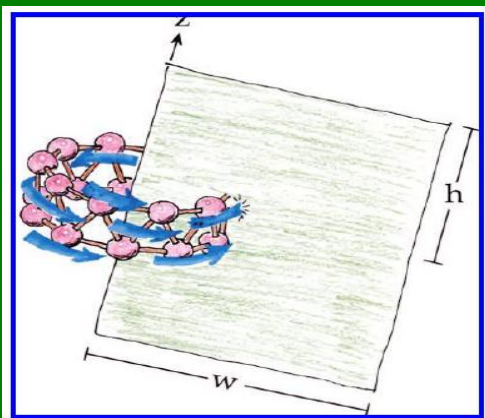
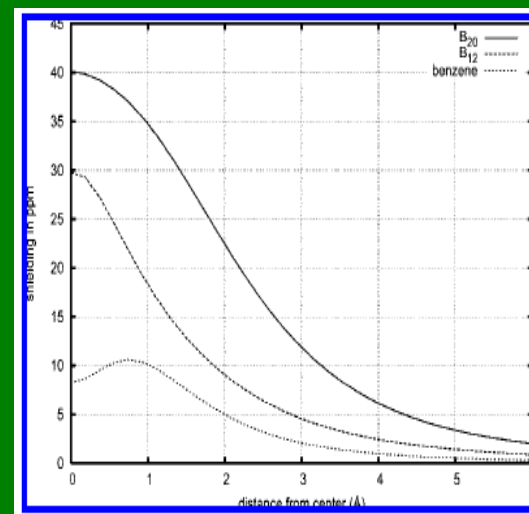
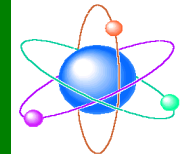


TABLE 2: Integrated Induced Currents for Selected Molecules in nA/T^a

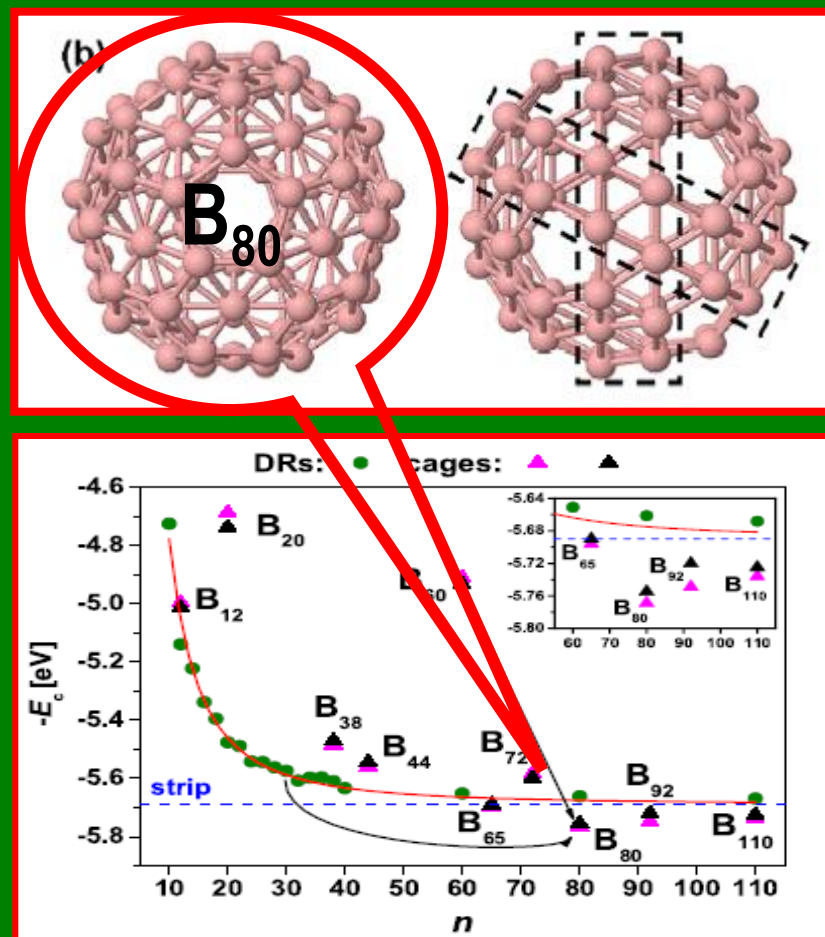
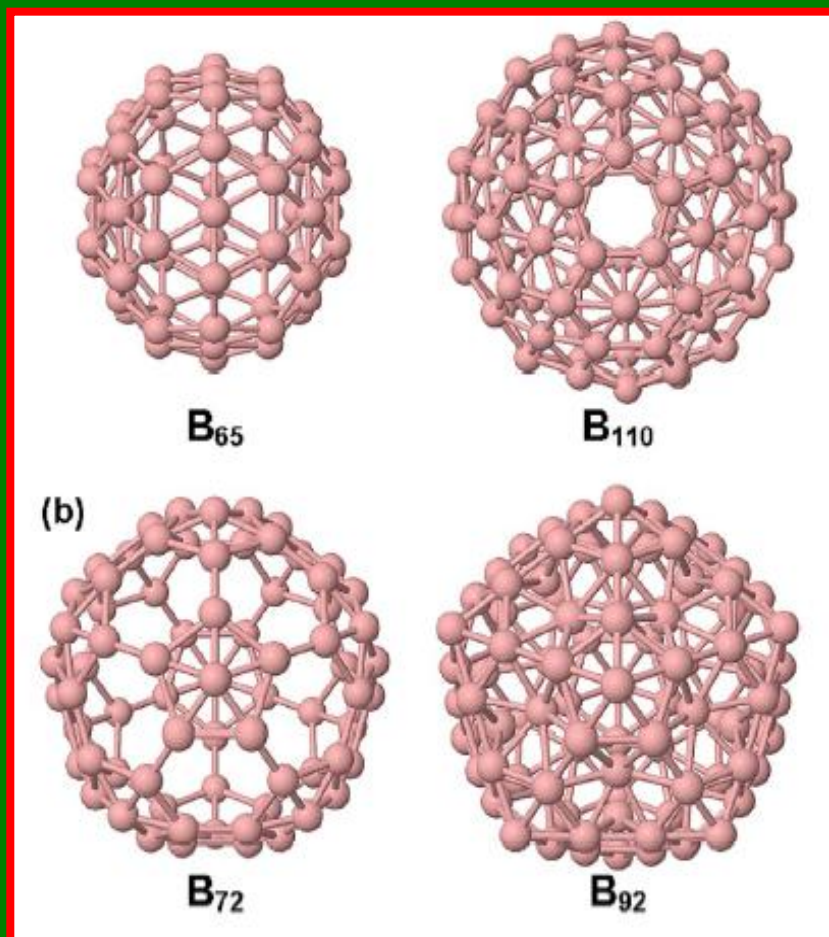
	sym	total current	diamagnetic	paramagnetic	NICS
B ₁₆	D_{8d}	31	33	-1	-33
B ₂₀	D_{10d}	42	43	-1	-40
B ₂₄	D_{12d}	50	51	-1	-35
B ₁₈	C_{2h}	-117	11	-128	+62
B ₂₂	C_i	-121	8	-130	+90
B ₁₂	C_{3v}	25	25	0	-30
C ₆₀ ^{10+ b}	I_h	60	81	-21	-82
C ₆ H ₆	D_{6h}	12	17	-5	-8

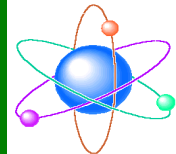




Boron Fullerenes

B. I. Yakobson et al., PRL 98, 166804 (2007)

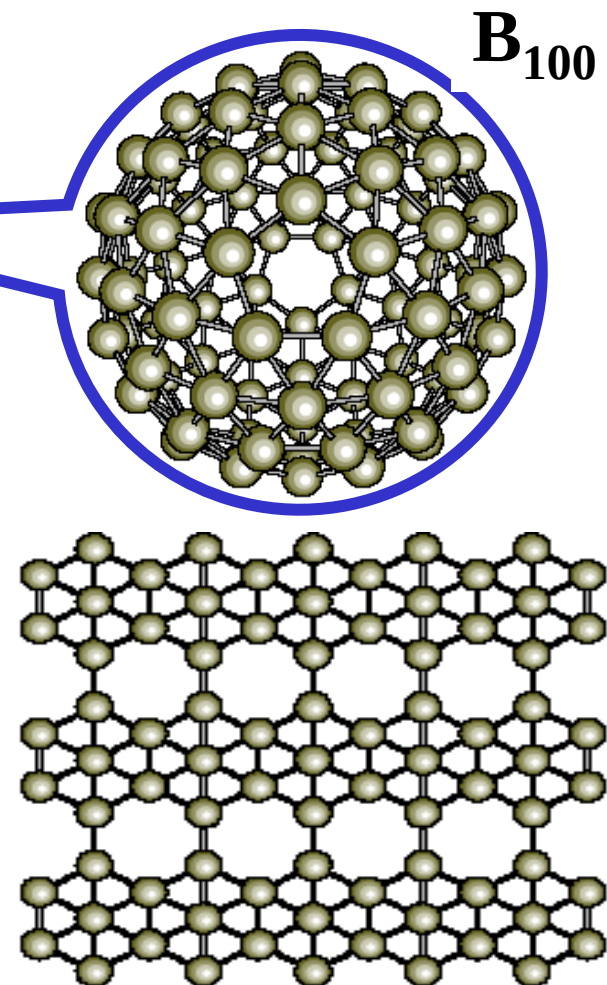
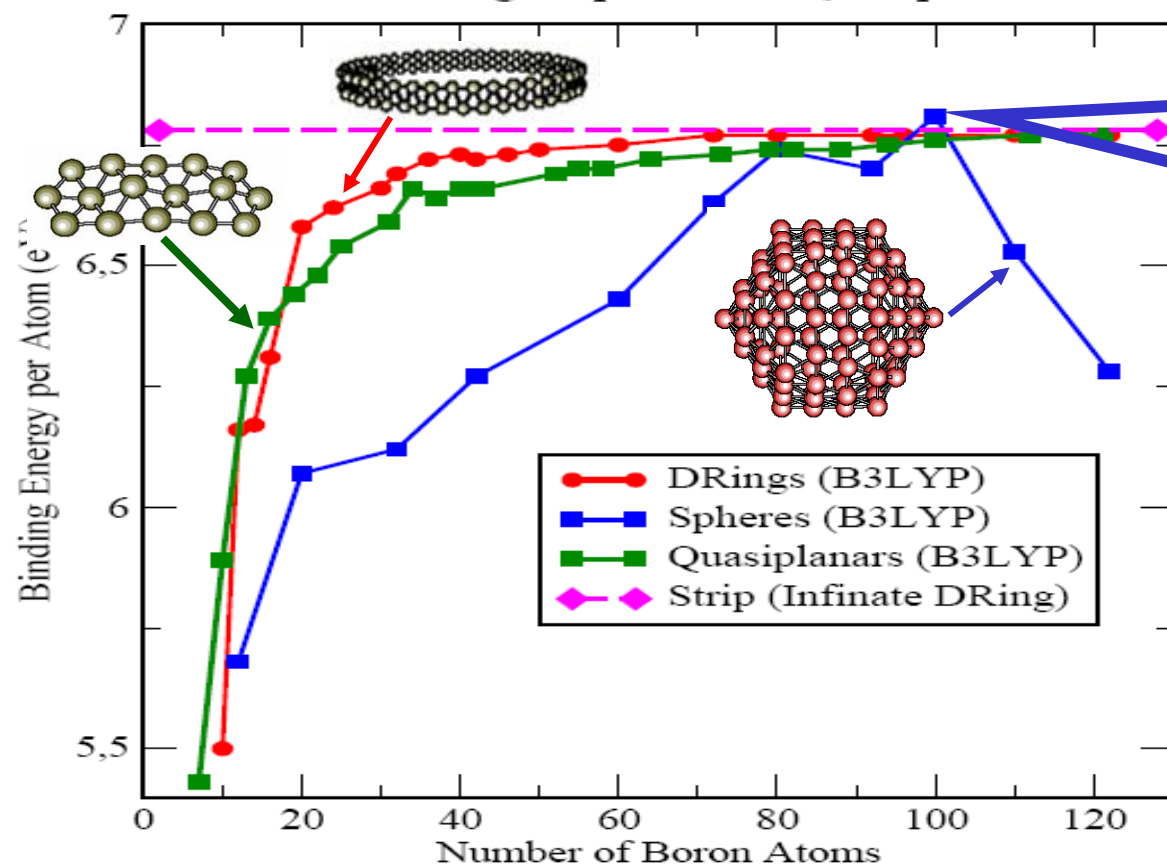


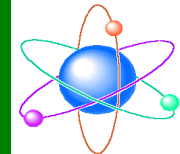


Boron Fullerene-like Nanospheres

Pandey & Boustani, J. Phys. Submitted (2008)

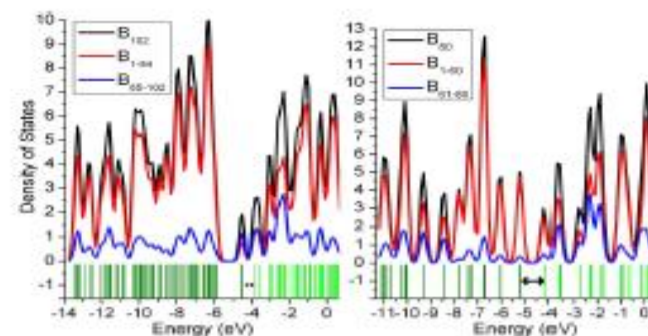
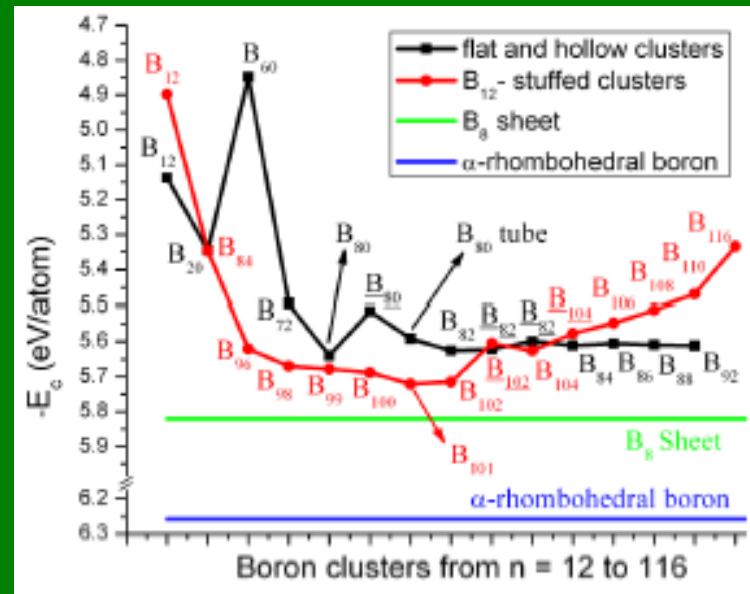
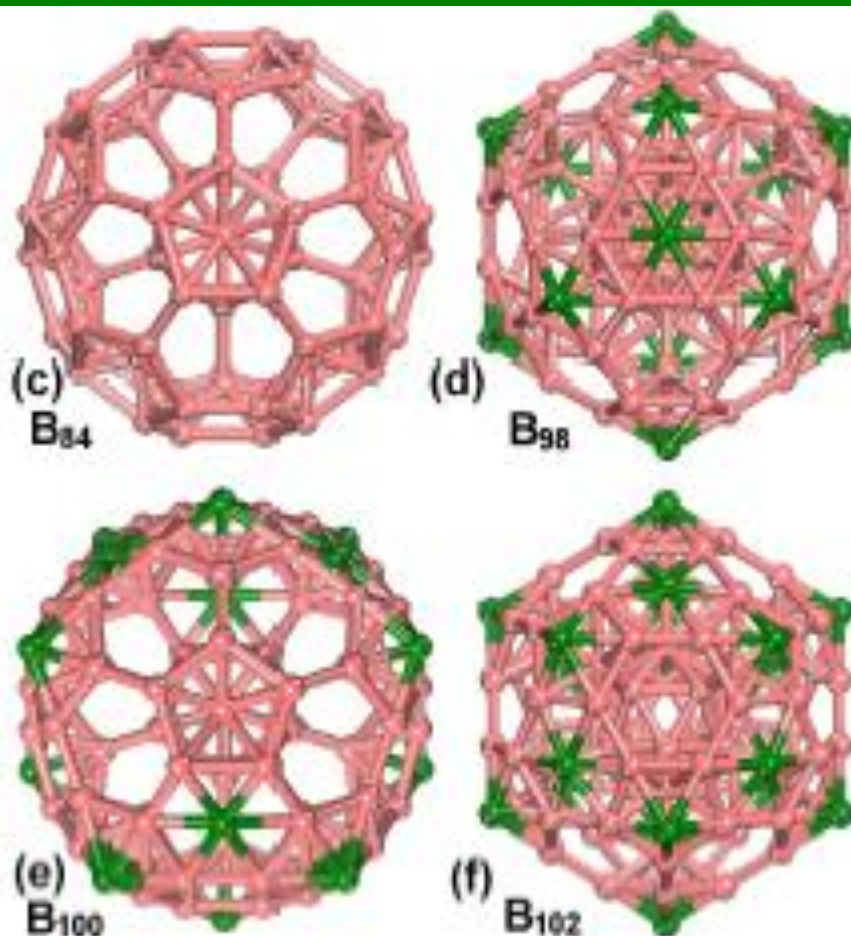
Stability of Boron Fullerenes
Double Rings, Spheres & Quasiplanars

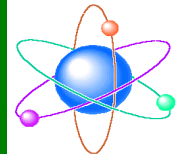




Stuffing Improves the Stability of Fullerenelike Boron Clusters

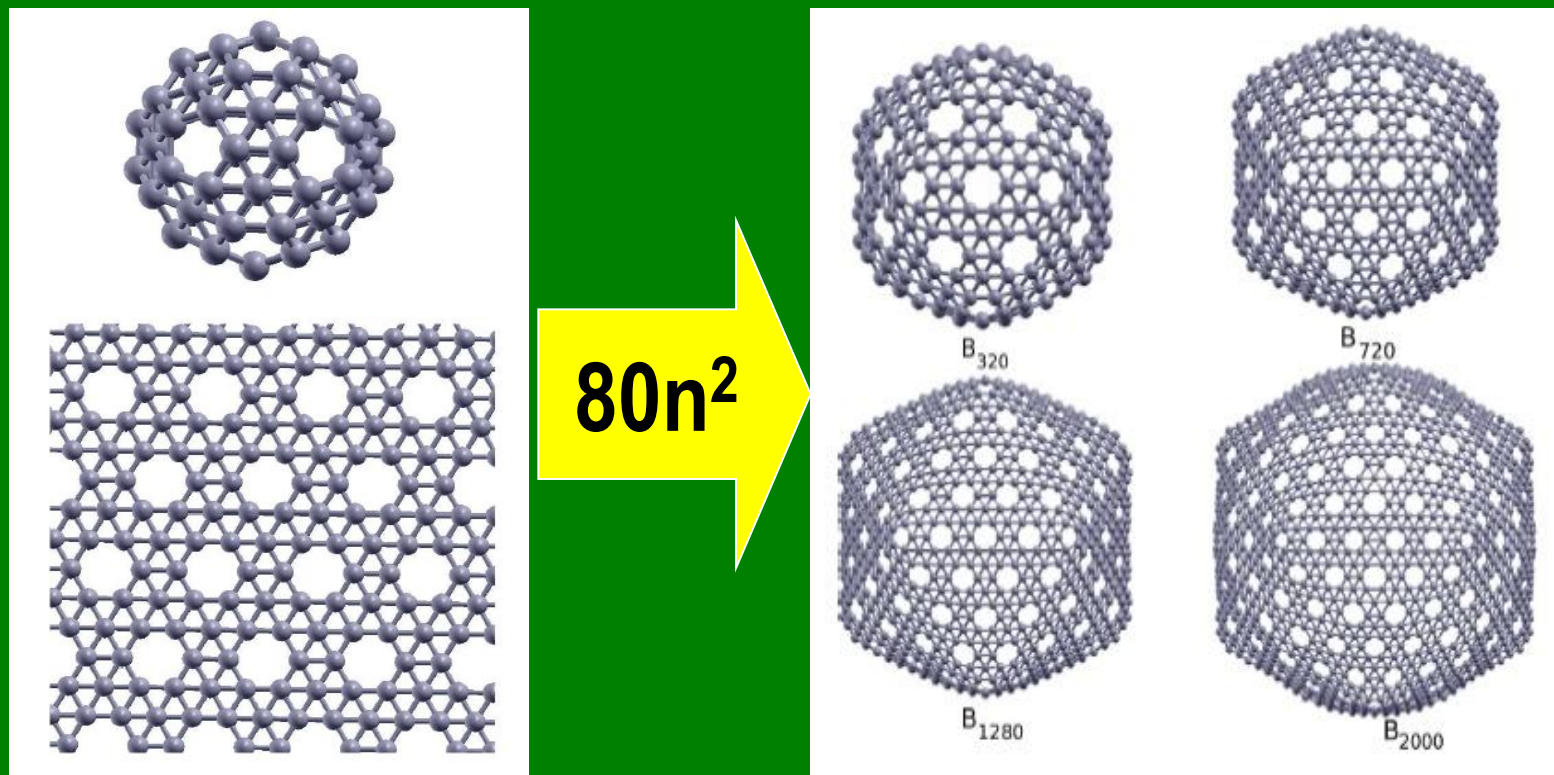
Prasad and Jemmis, PRL 100, 165504 (2008)



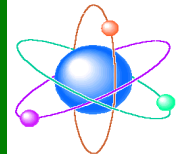


Boron fullerenes: from B_{80} to hole doped boron sheets

Amy Lui et al., PRB 79, 161403 (2009)



**Boron Fullerenes become metallic around $n=4-5$
Their $60n^2$ carbon cousins are semiconductors.**



Probing Properties of Boron α -Tubes by *Ab Initio* Calculations

Yakobson et al., Nanoletters, 8, 1314 (2008)

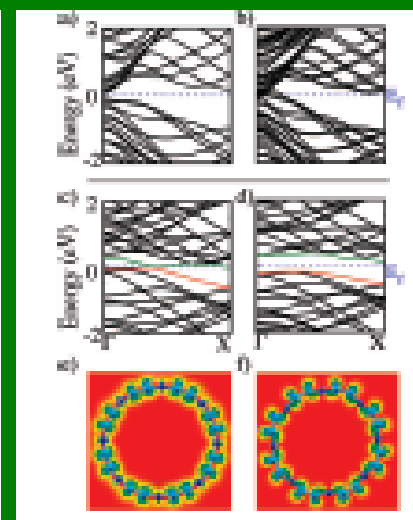
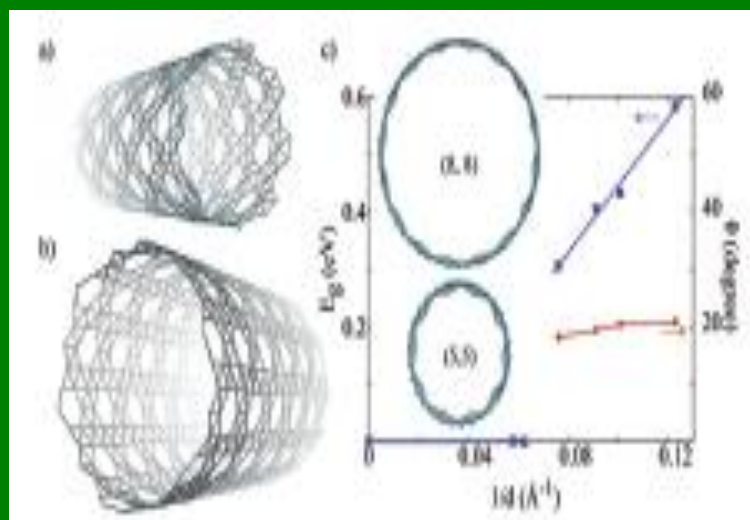
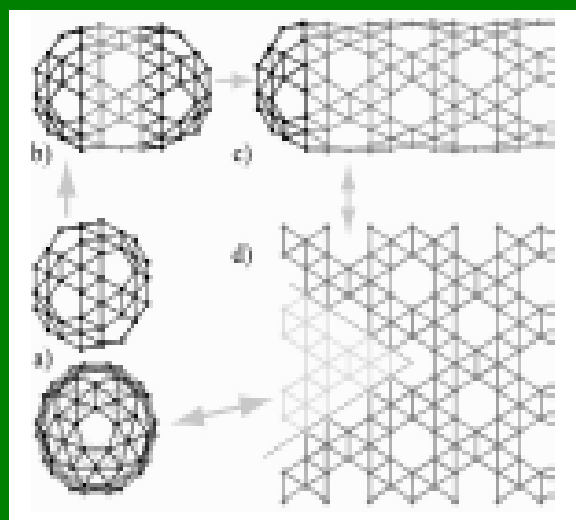
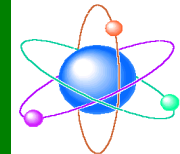


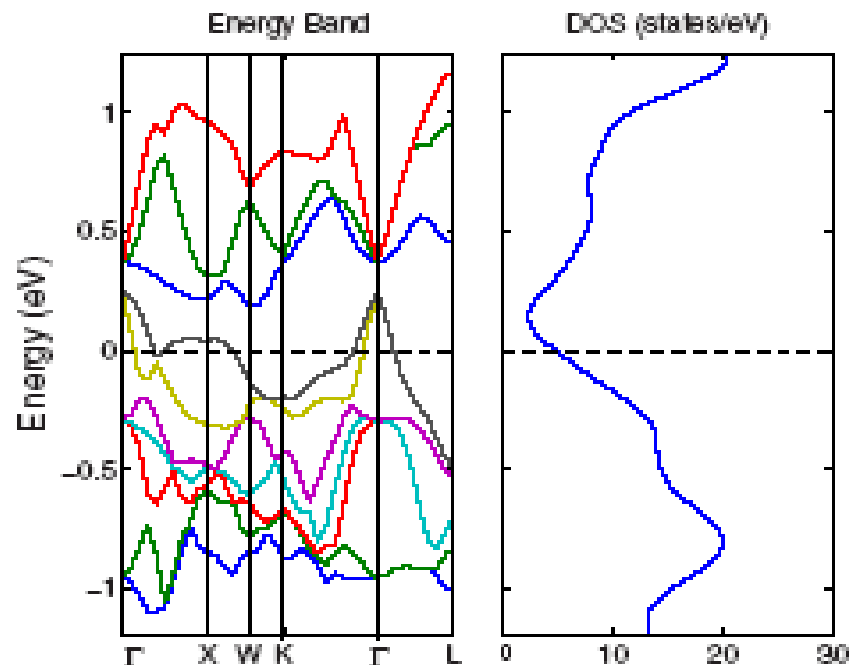
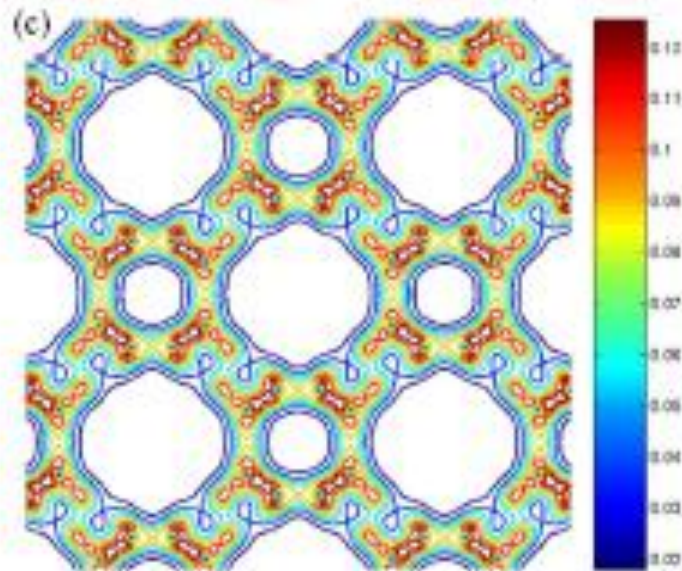
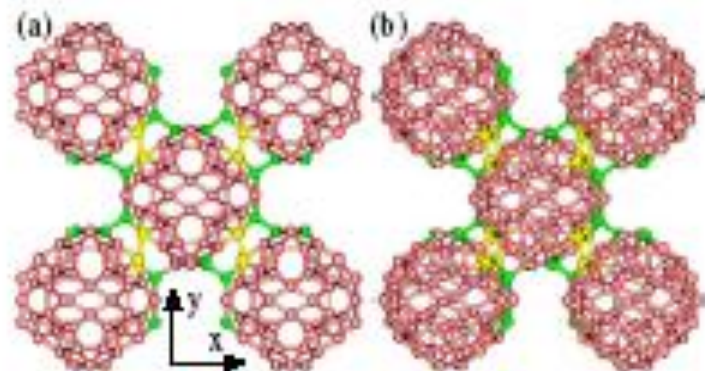
Table 1. Calculated Stiffness (C), Poisson Ratio (ν), and Radial Breathing Mode Frequencies (f_{RBM}) of Boron α -Tubes

nanotubes	diameter ($\text{\AA}$)	C (N/m)	ν	f_{RBM} (cm^{-1})
(5,5)	8.13	209.4	0.18	238.9
(9,0)	8.63	206.7	0.21	224.8
(6,6)	9.93	202.1	0.26	195.9
(12,0)	11.31	204.6	0.21	170.6
(7,7)	11.37	215.2	0.20	173.7
(8,8)	13.13	214.0	0.21	150.2
(18,0)	16.50	217.5	0.15	119.2

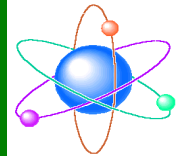


Face-centered-cubic B₈₀ metal: Density Funktional Theory Calculations

Yan, Zheng, and Su, PRB 77, 224106 (2008)



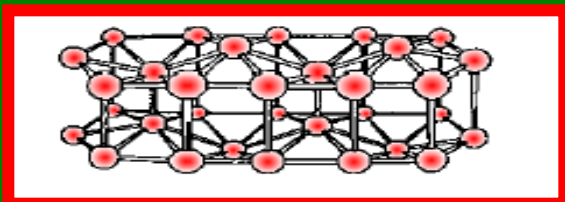
The total energy of B₈₀ fcc solid is 0.23 eV/atom lower than the isolated B₈₀ fullerene



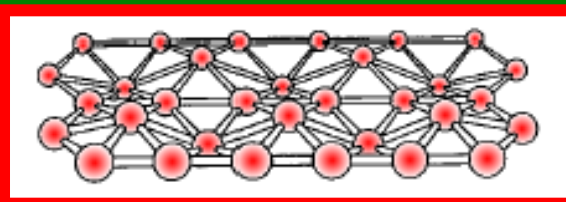
Boron Sheets

Boustani Surf. Sci., 1997
Kunstmann & Quandt 2008

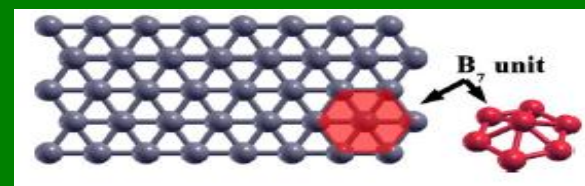
Double Layers



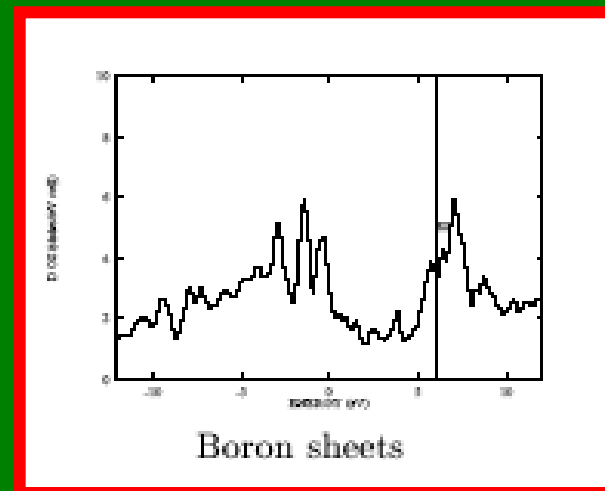
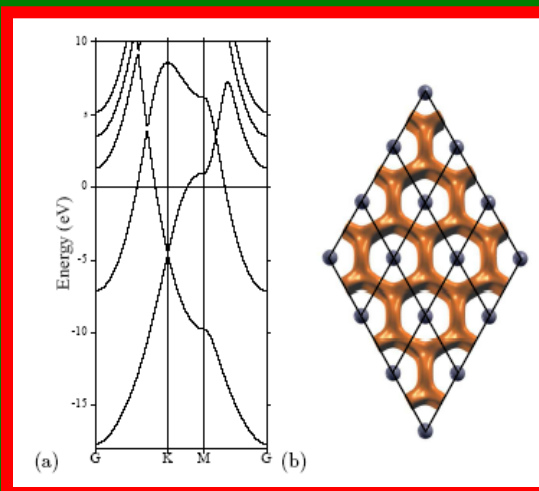
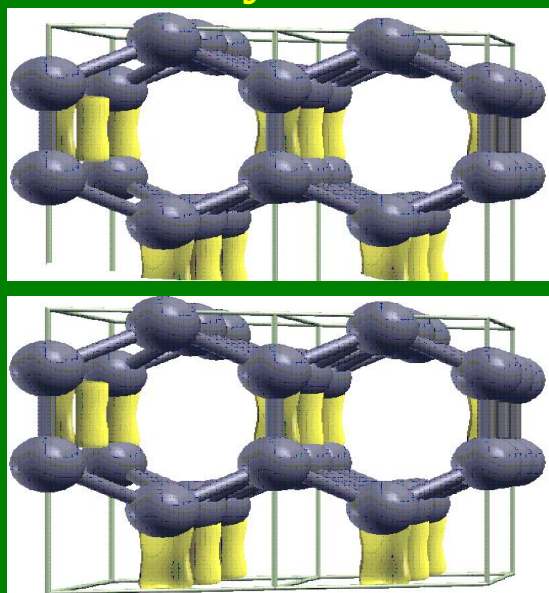
Single Layer



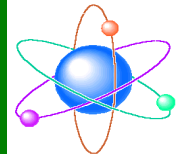
Infinite Sheet



Multi Layers

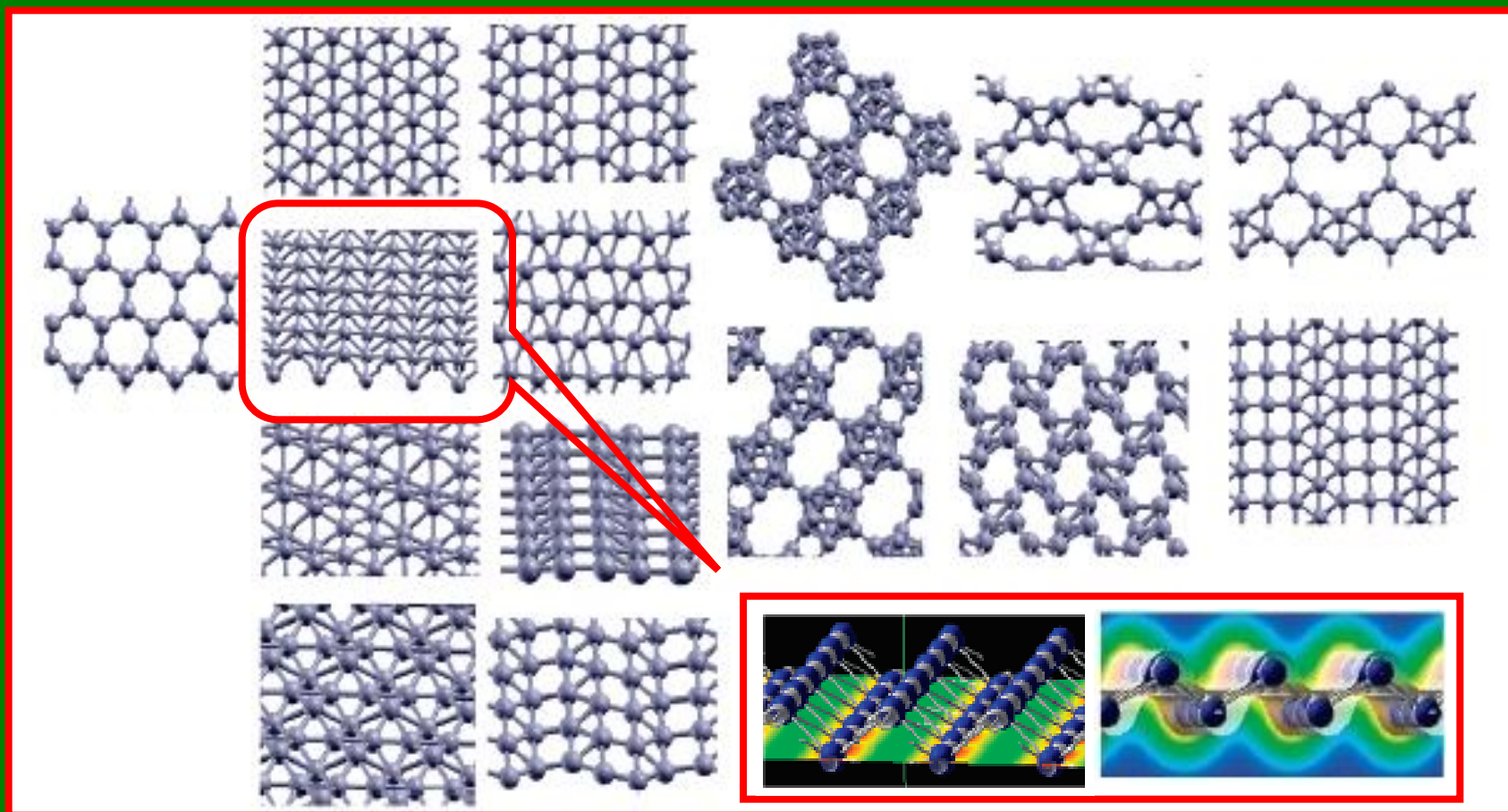


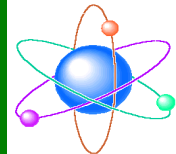
Band Structure, Electron Density, DOS : metallic



2D Boron Sheets

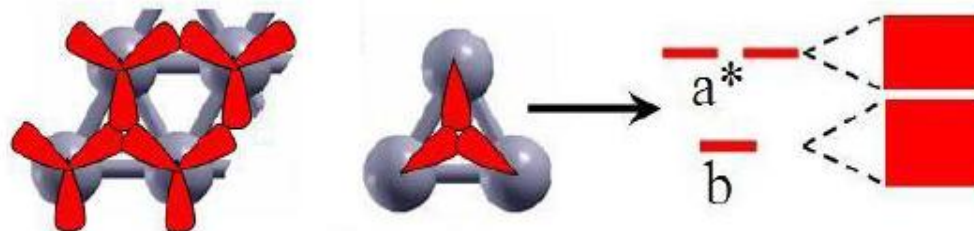
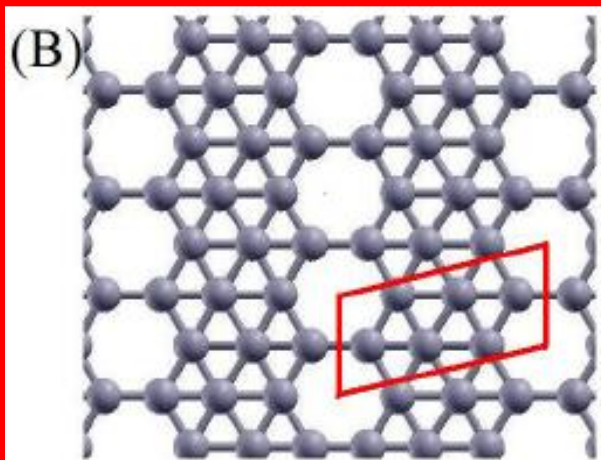
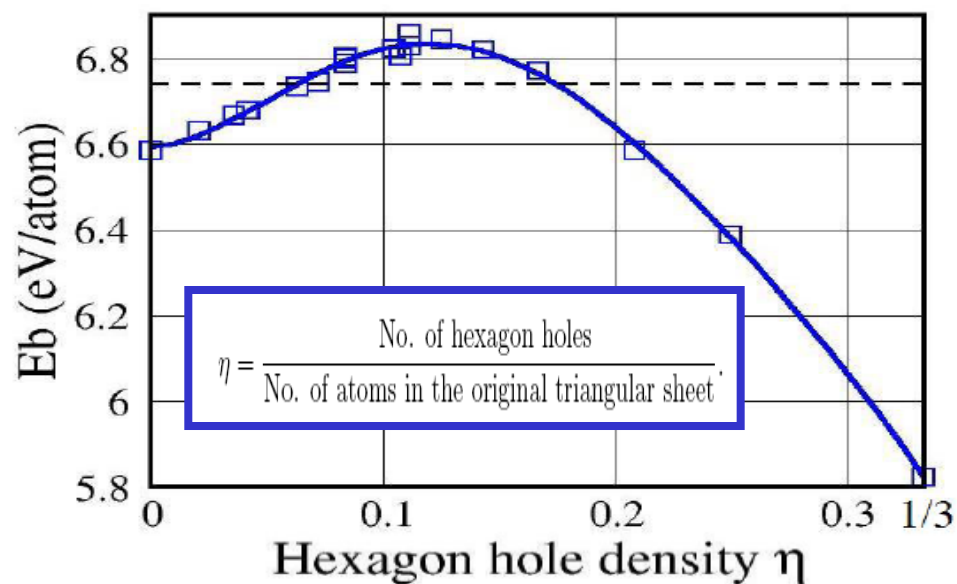
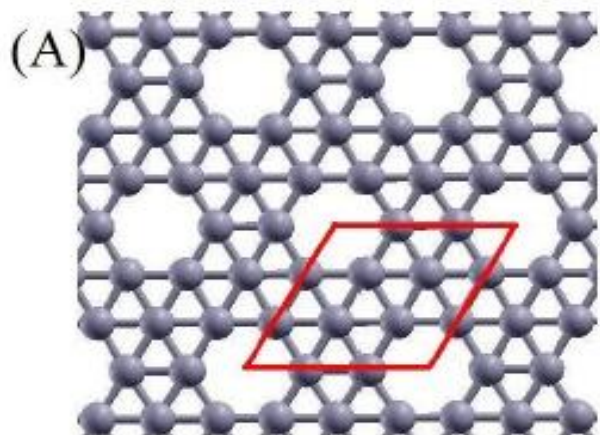
Lau & Pandey, JPC C, 111, 2906 (2007)

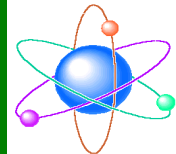




2D Boron Sheets with Hexagonal Motives

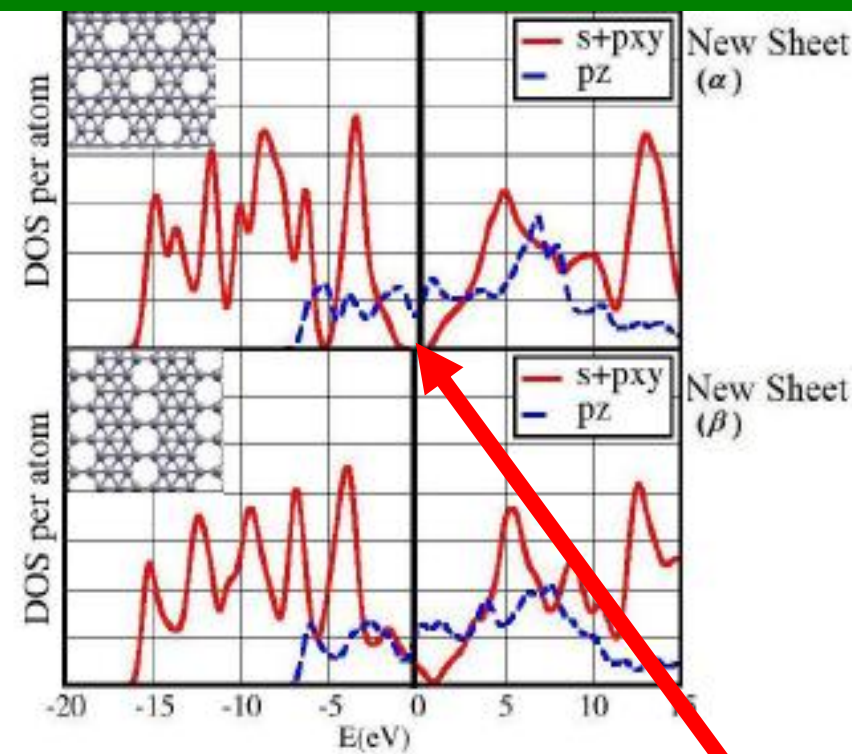
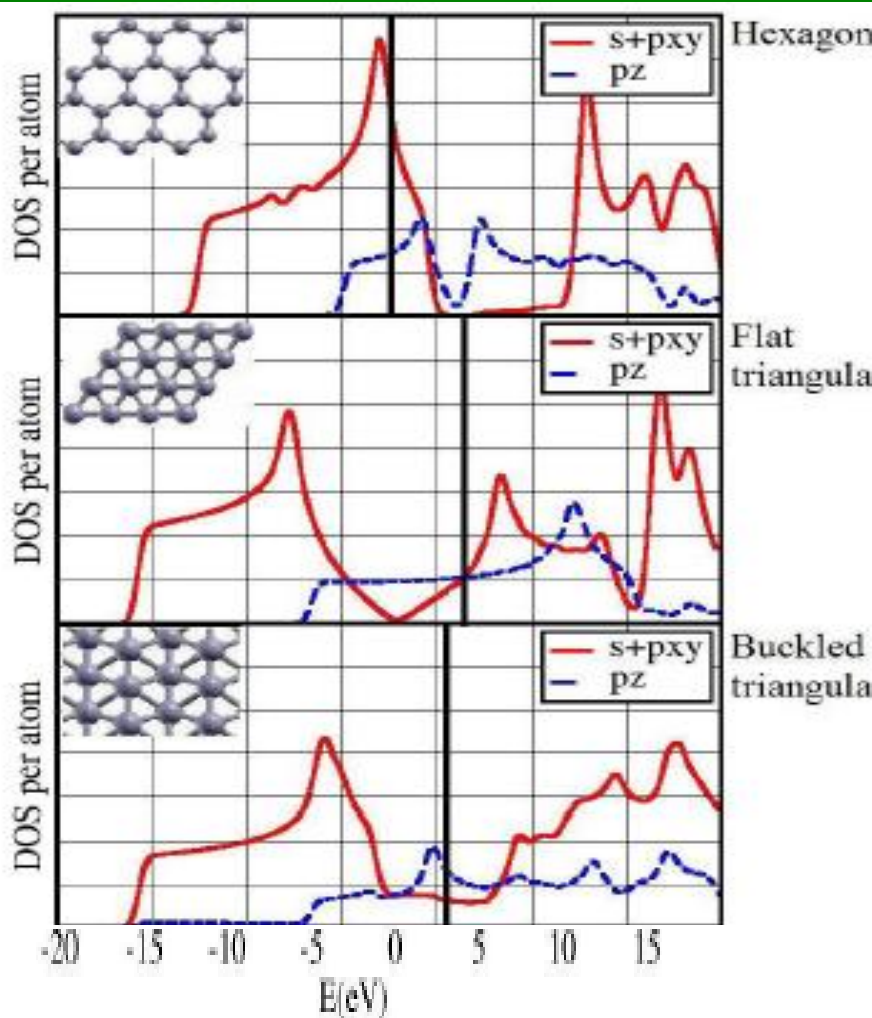
Tang & Ismail-Beigi, PRL, 99, 115501 (2007)



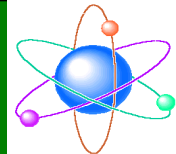


2D Boron Sheets with Hexagonal Motives

Tang & Ismail-Beigi, PRL, 99, 115501 (2007)

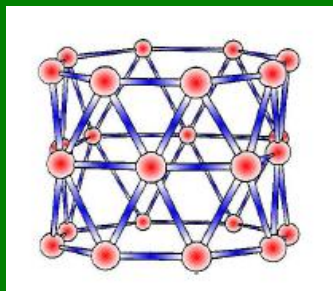


Highest stability occurs when E_f places precisely at the zero-point of In-Plane PDOS filling all available in-plane bonding states and none of the anti-bonding ones.

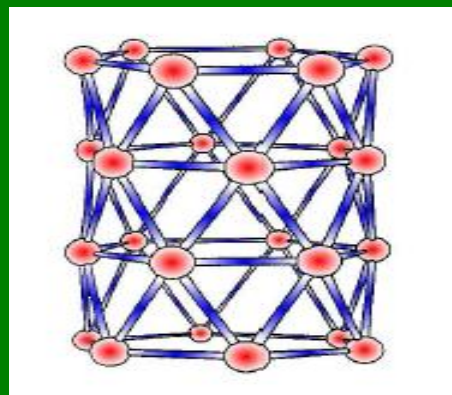


Single Wall Boron Nanotubes

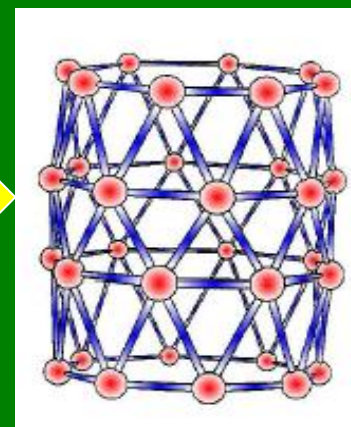
Boustani & Quandt, EPL 1997, JCP 1999



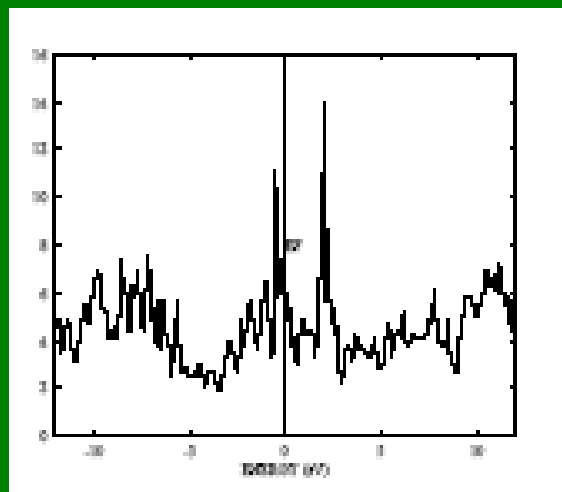
24



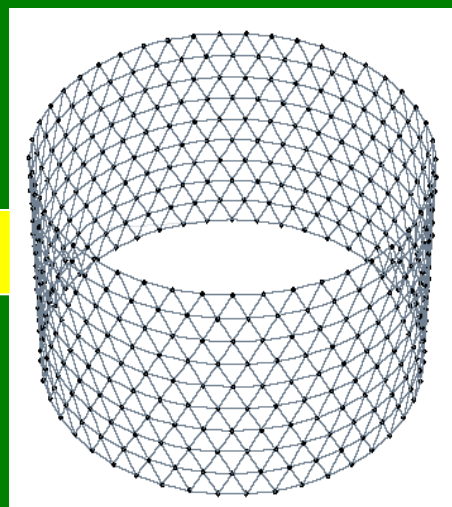
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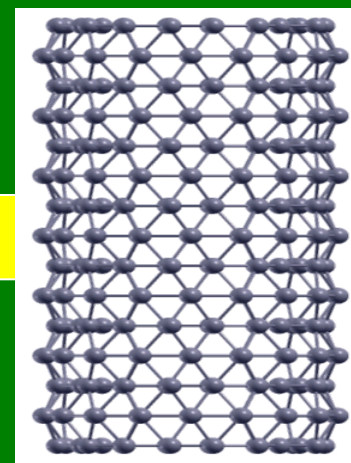
Metallic



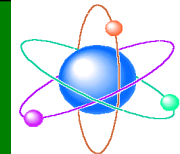
DOS



450

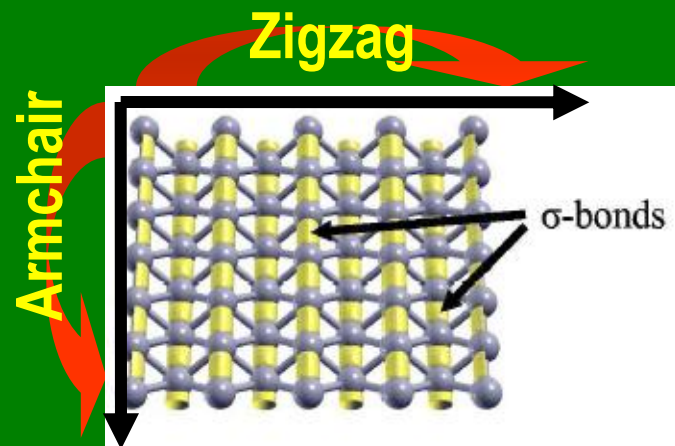


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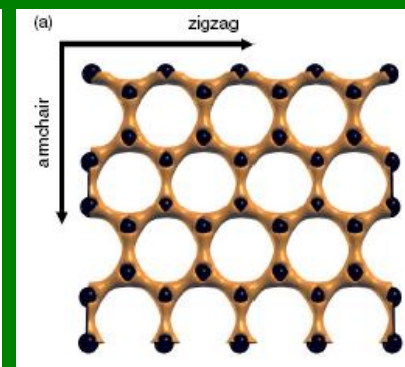
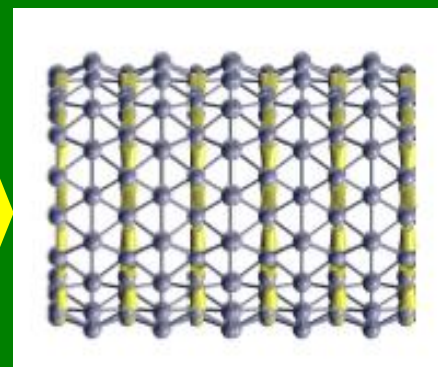


Control the Radius & Chirality of BNTs

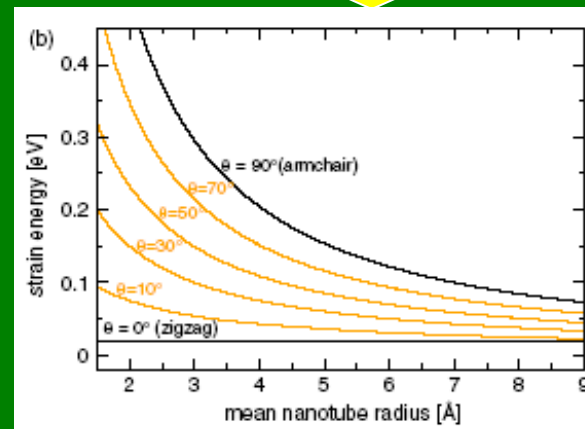
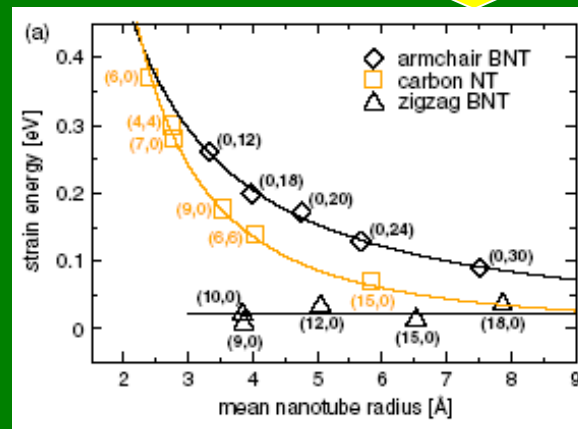
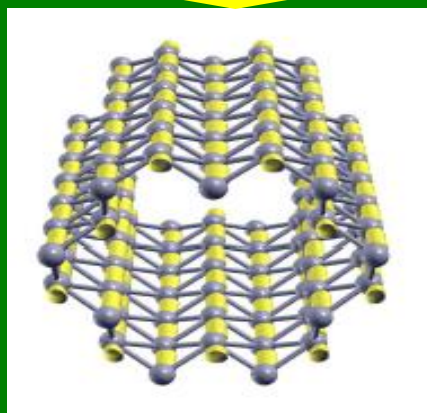
Kunstmann, Quandt & Boustani, Nanotechnology 18, 155703 (2007)



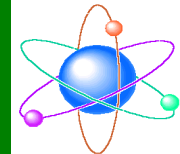
Armchair
(0,N)



Zigzag (N,0)

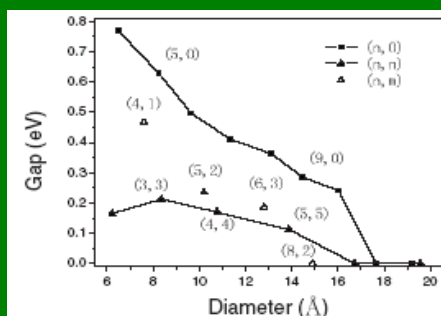
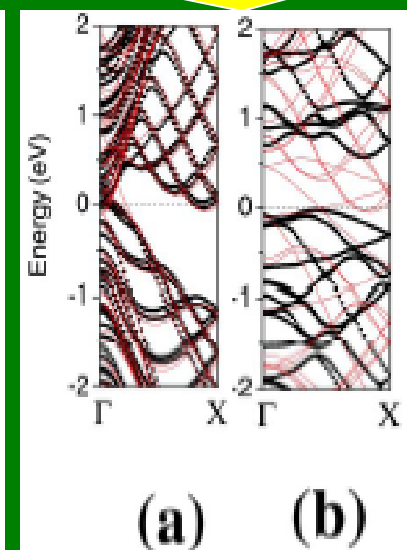
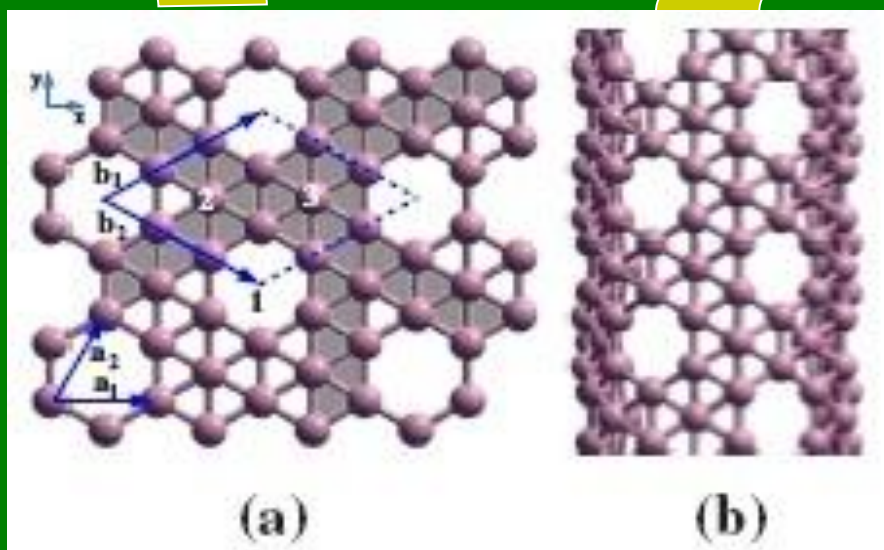
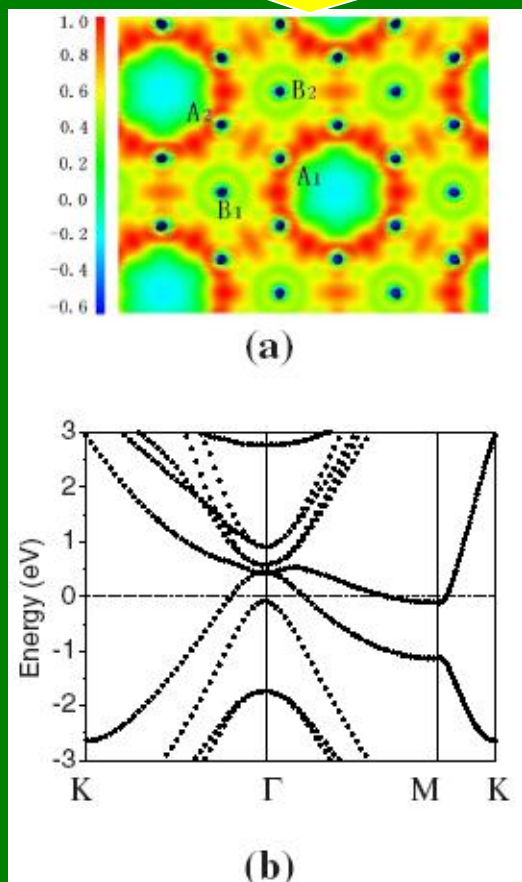


Strain Energy

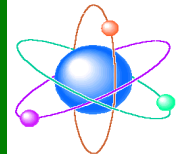


Ab initio Prediction of Boron Sheets and Nanotubes

X. Yang, Y. Ding, and J. Ni, PRB 77, 041402R (2008)

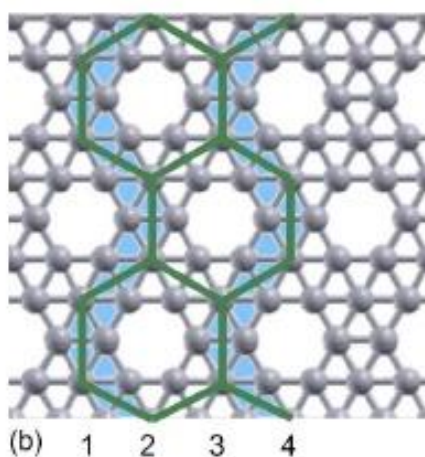
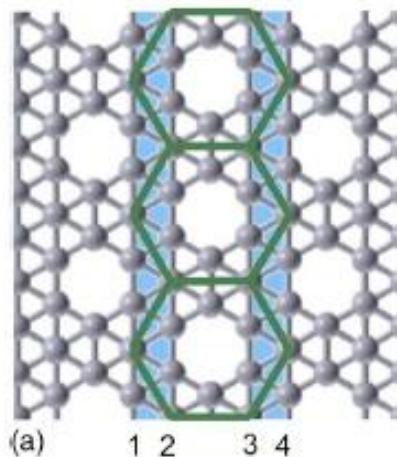
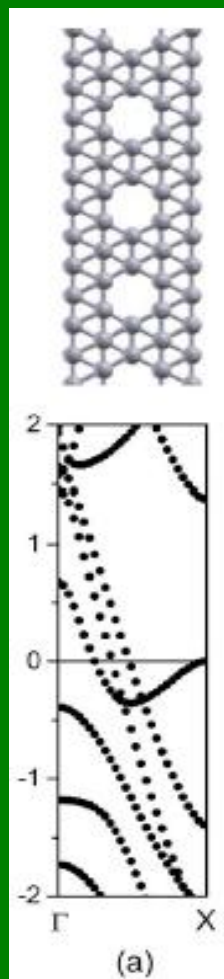


The boron sheet is a metal and the nanotubes can be either metals or semiconductors gap 0.1–0.8 eV dependent on diameter & chirality.

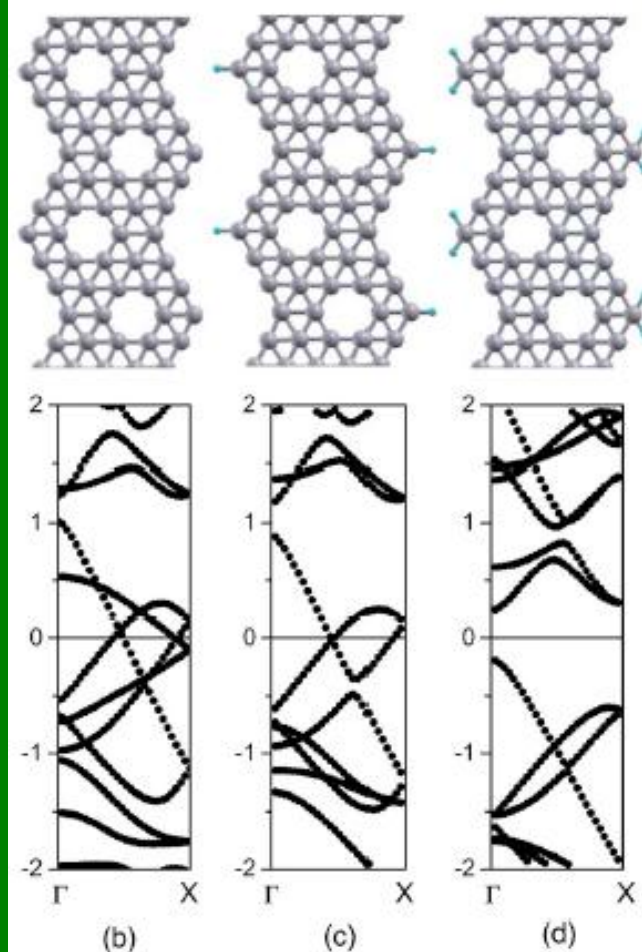


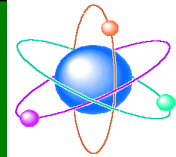
Electronic structures of boron nanoribbons

Y. Ding, X. Yang, and J. Ni, APL 93, 043107 (2008)



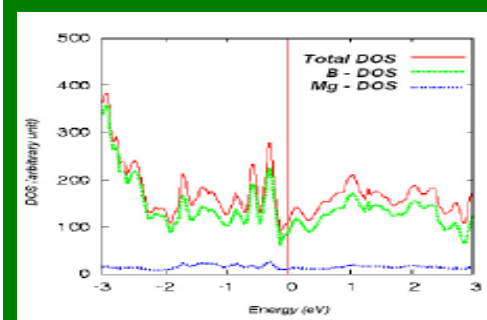
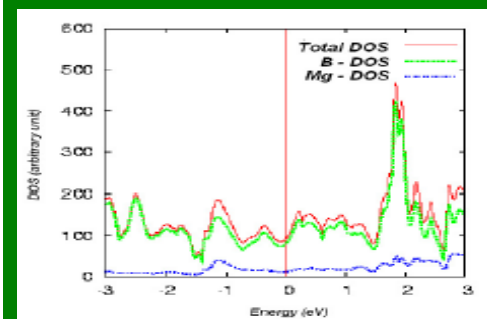
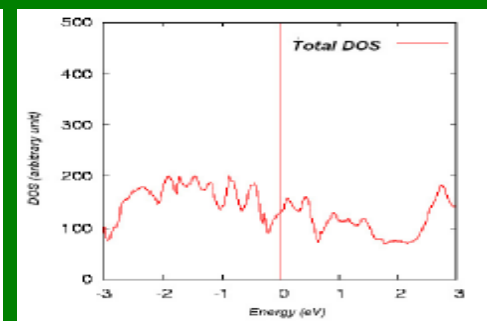
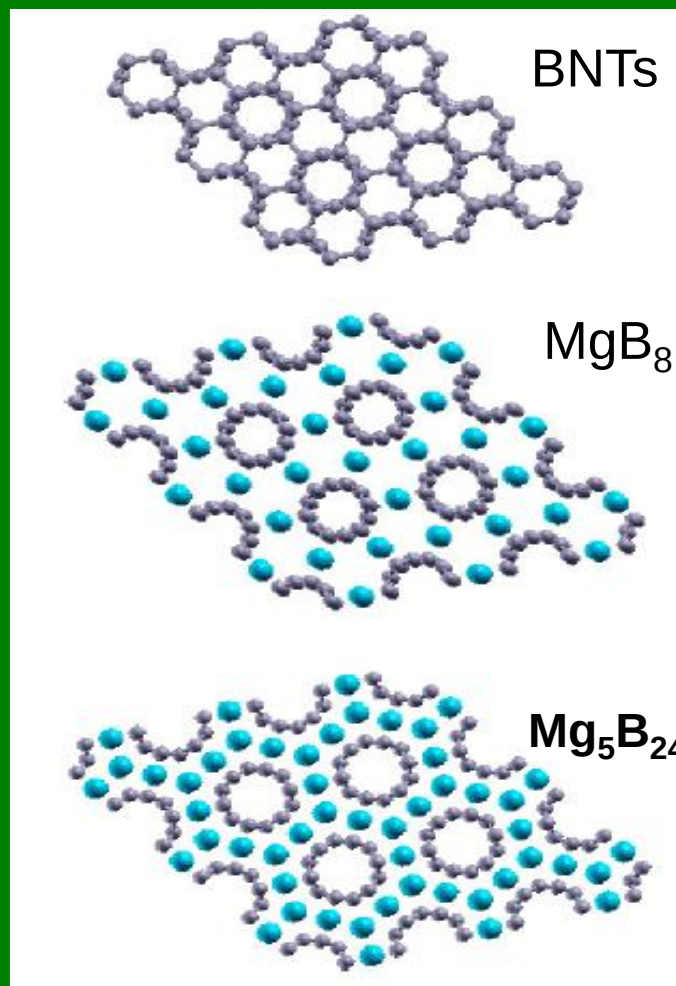
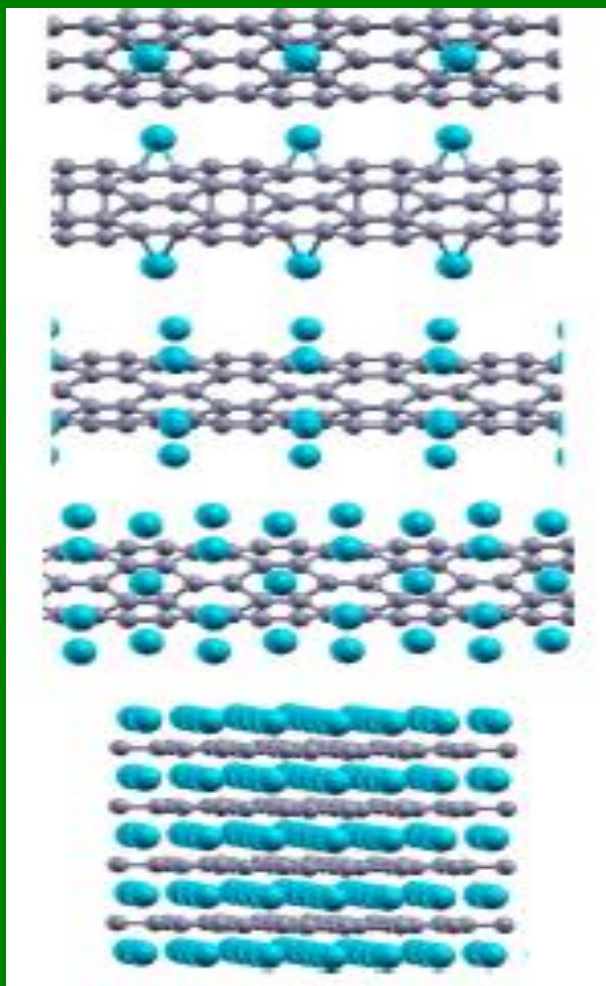
The boron nanoribbons with different edges are metals. The H-terminated nanoribbons are semi-conductors with a Band gap of 0.5 eV

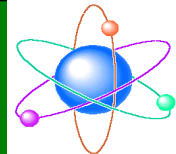




Structure and stability of Mg-intercalated boron nanotubes and crystalline bundles

Lau, Orlando & Pandey, J. Phys.: Condens Matter 21, 045304 (2009)

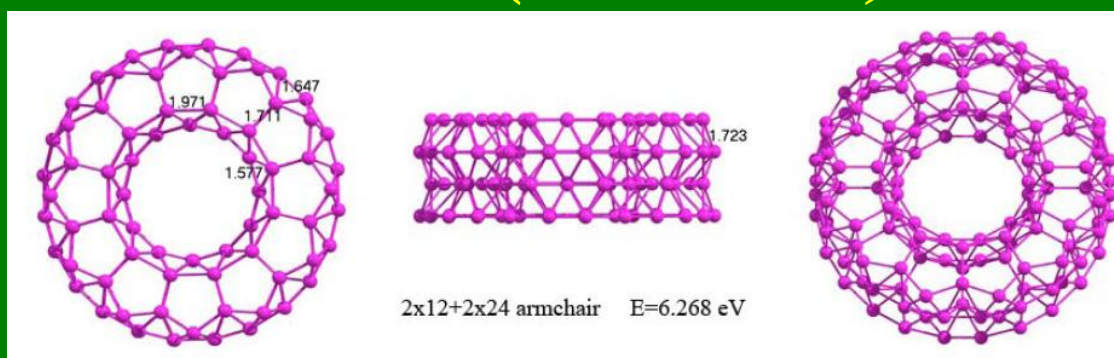




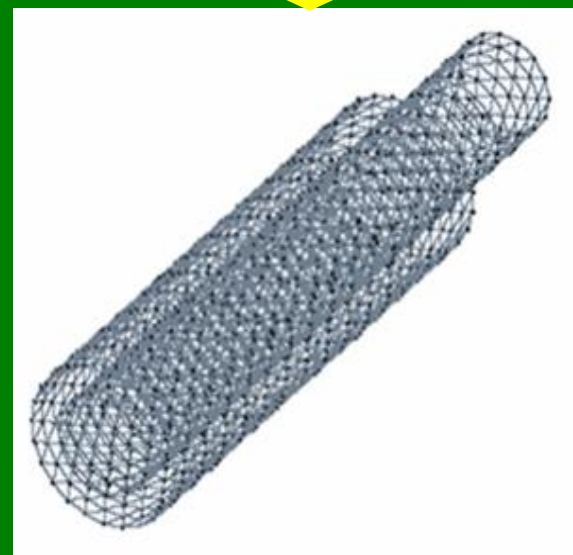
Double Wall Boron Nanotubes

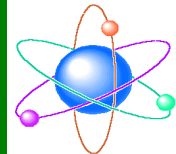
Sebetci, Mete & Boustani, J. Phys. Chem. of Solids, 69, 2004 (2008)

- *Armchair* ($2 \times 12 + 2 \times 24$)



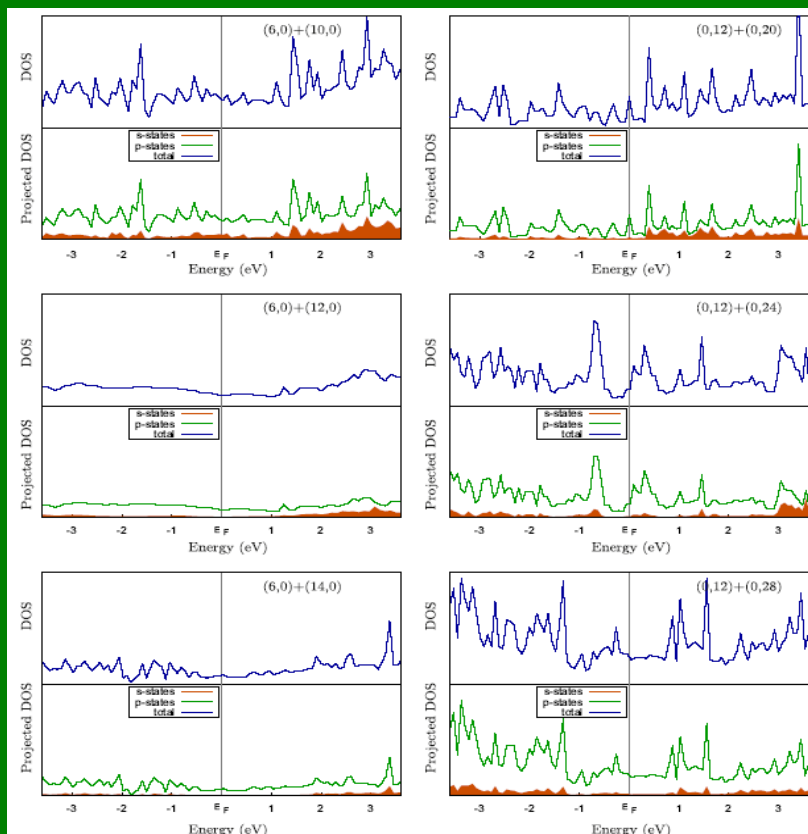
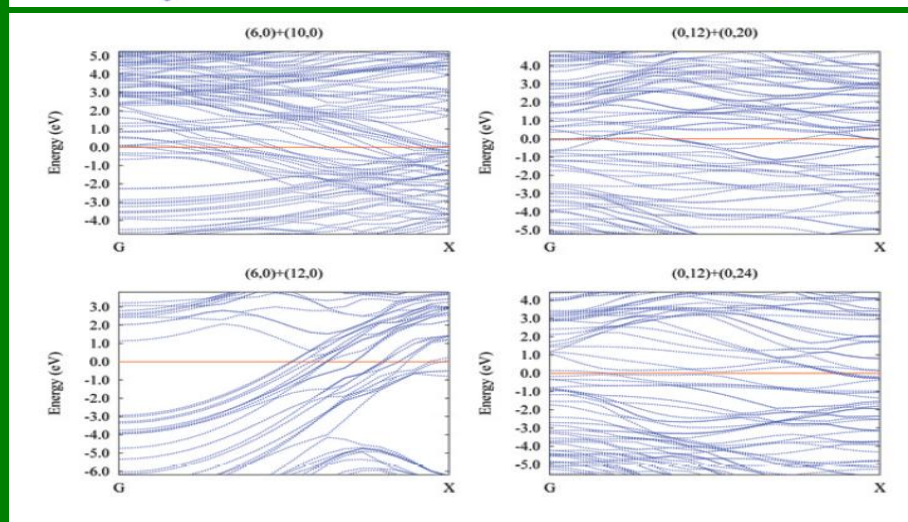
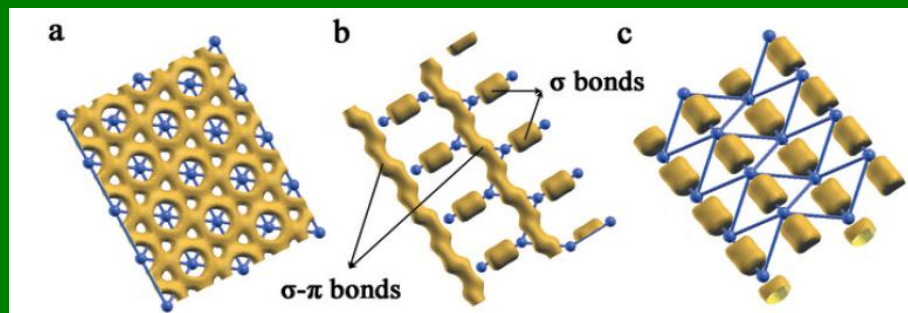
- *Zigzag* ($4 \times 12 + 4 \times 24$)



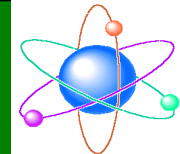


Double Wall Boron Nanotubes

Sebetci, Mete & Boustani, J. Phys. & Chem. of Solids, 69, 2004 (2008)



Band structure and density of states DOS of s-band
and p-bands of zigzag and armchair DWBNTs

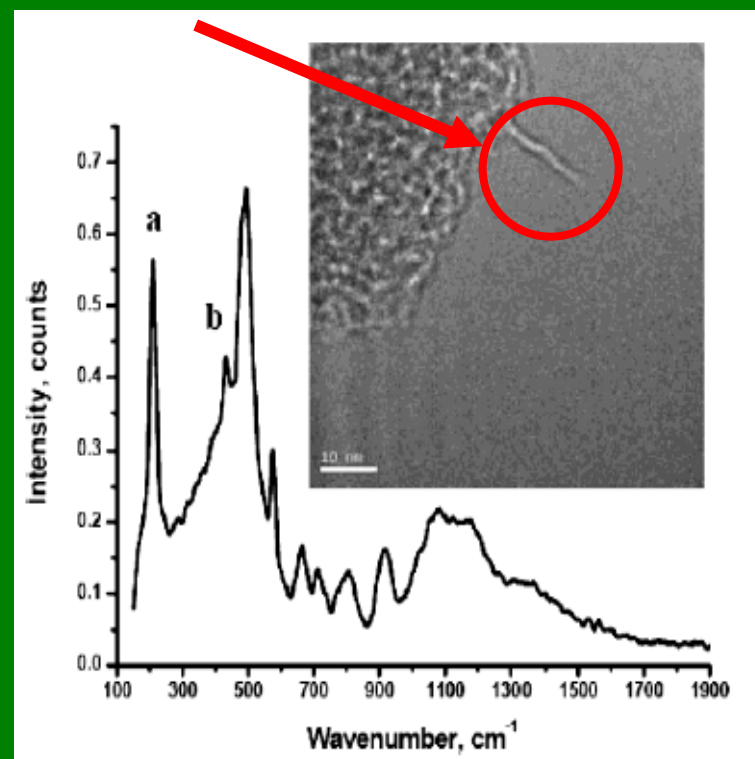
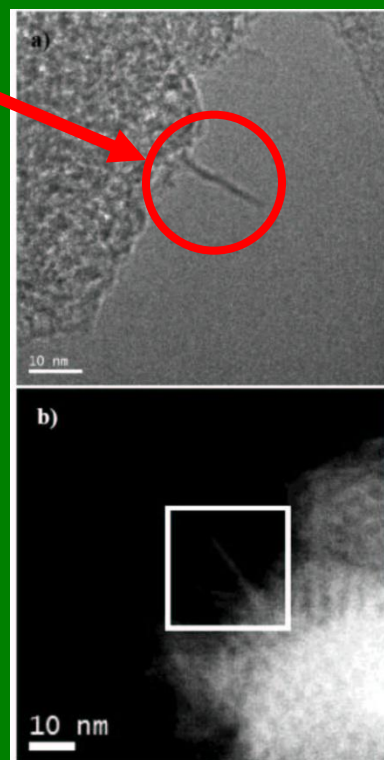


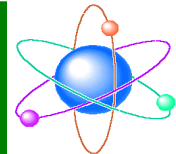
Experimental Confirmation of Single-Walled Boron Nanotubes

Theory : Boustani & Quandt, *Europhys. Lett.* 39, 527 (1997)
Gindulyte, Lipscomb & Massa, *Inorg. Chem.* 37, 6544 (1998)

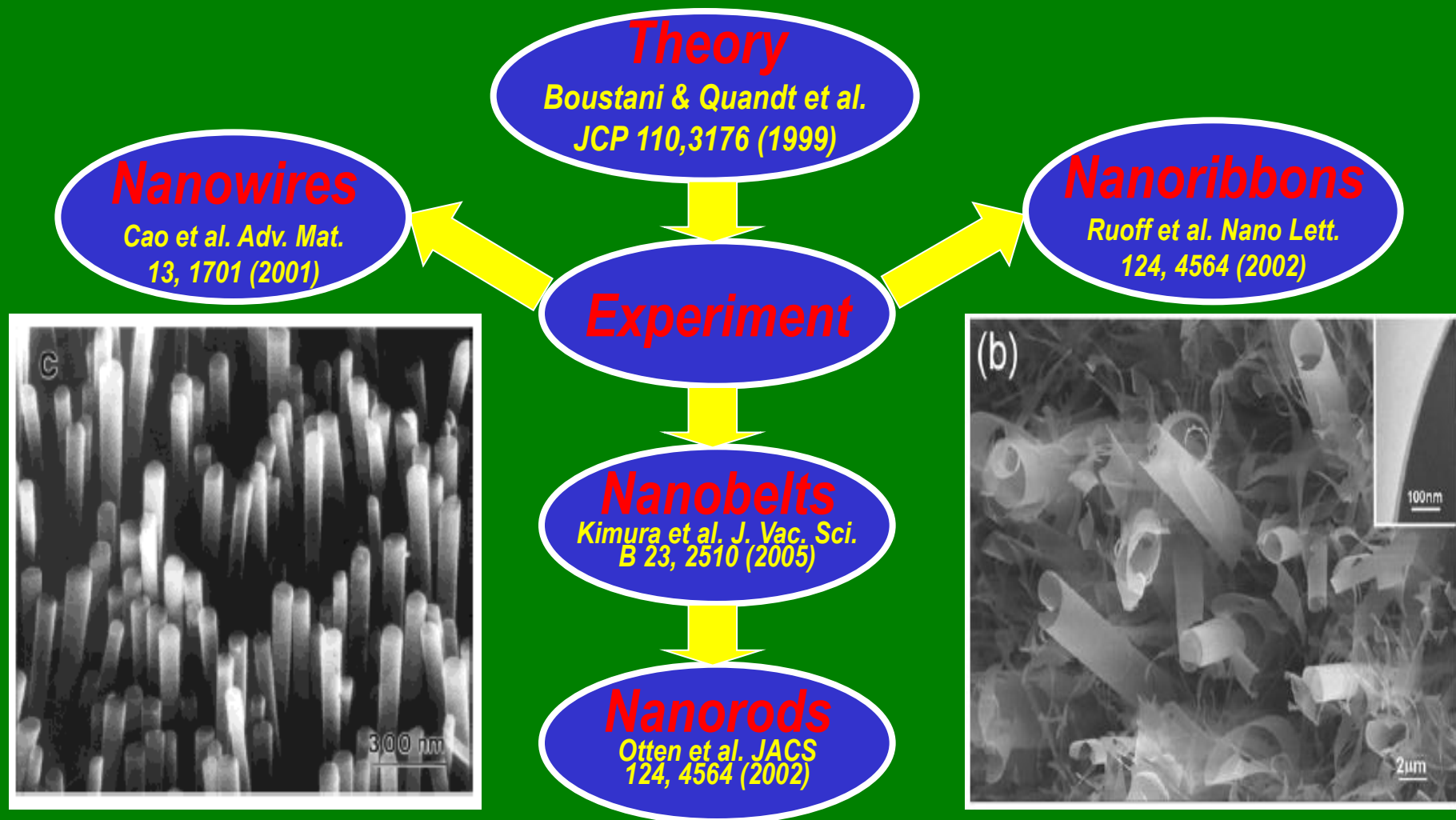
Experiment :

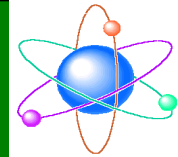
D. Ciuparu, R.F. Klie,
Y. Zhu & L. Pfefferle,
J. Phys. Chem. B 108,
3967 (2004)





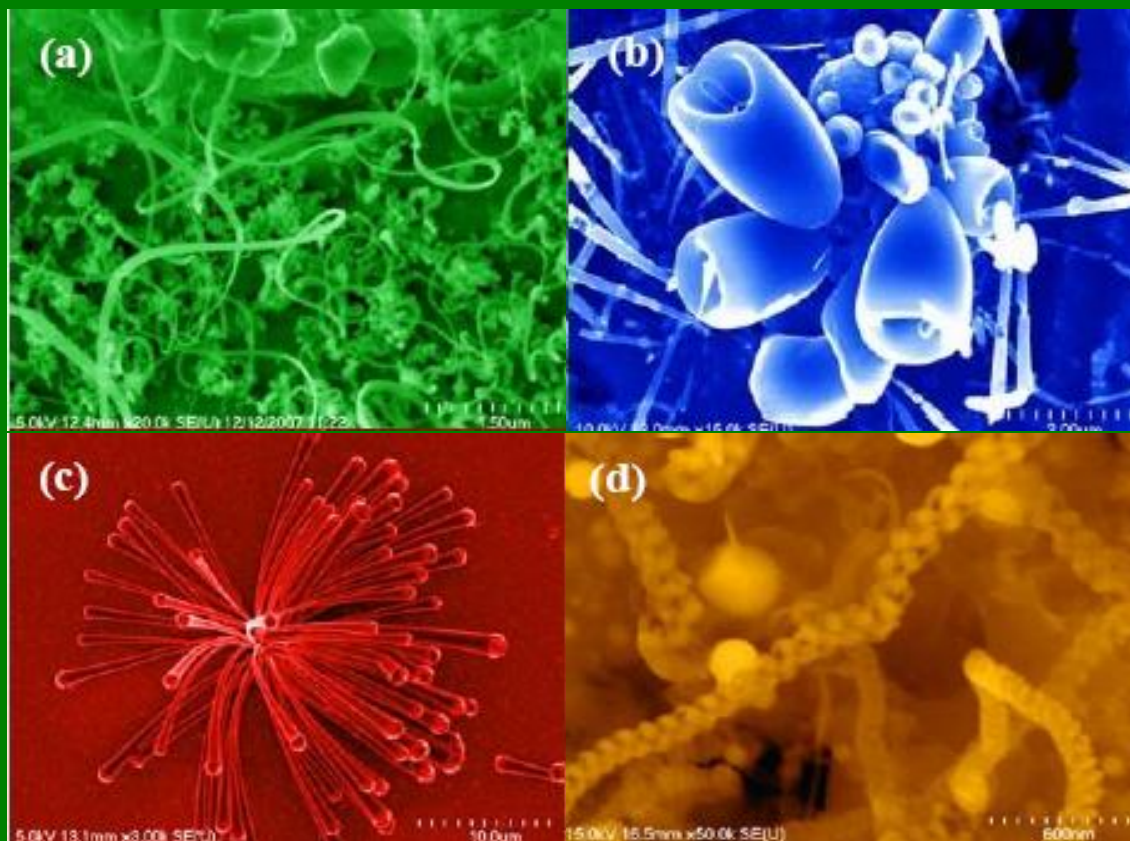
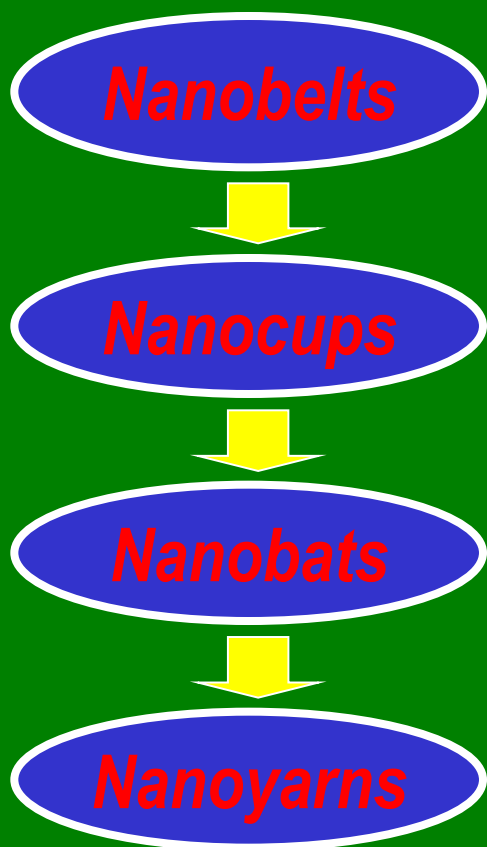
Experimental Developments of boron Nanostructures I

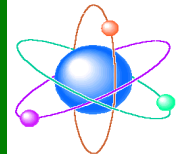




Experimental Developments of boron Nanostructures II

Yoke Khin Yap, Michigan TechnicaL University (MTU), 2008





Boron Clusters :

Boron Chemistry

Hydrogen Storage

Propulsion & Energetic

Embedding & Implantation

Boron Sheets and Nanotubes :

Semiconductors

Nanotechnology

Superconductors

Neutron Absorber, Fieldemission

Potential Applications

Doped α -Boron

Thermoelectric Devices

Coating & Ceramics

High-Temperature Devices

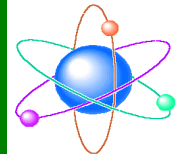
Electro-Optics & Corrosion

Boron Cages (Nanotubes !):

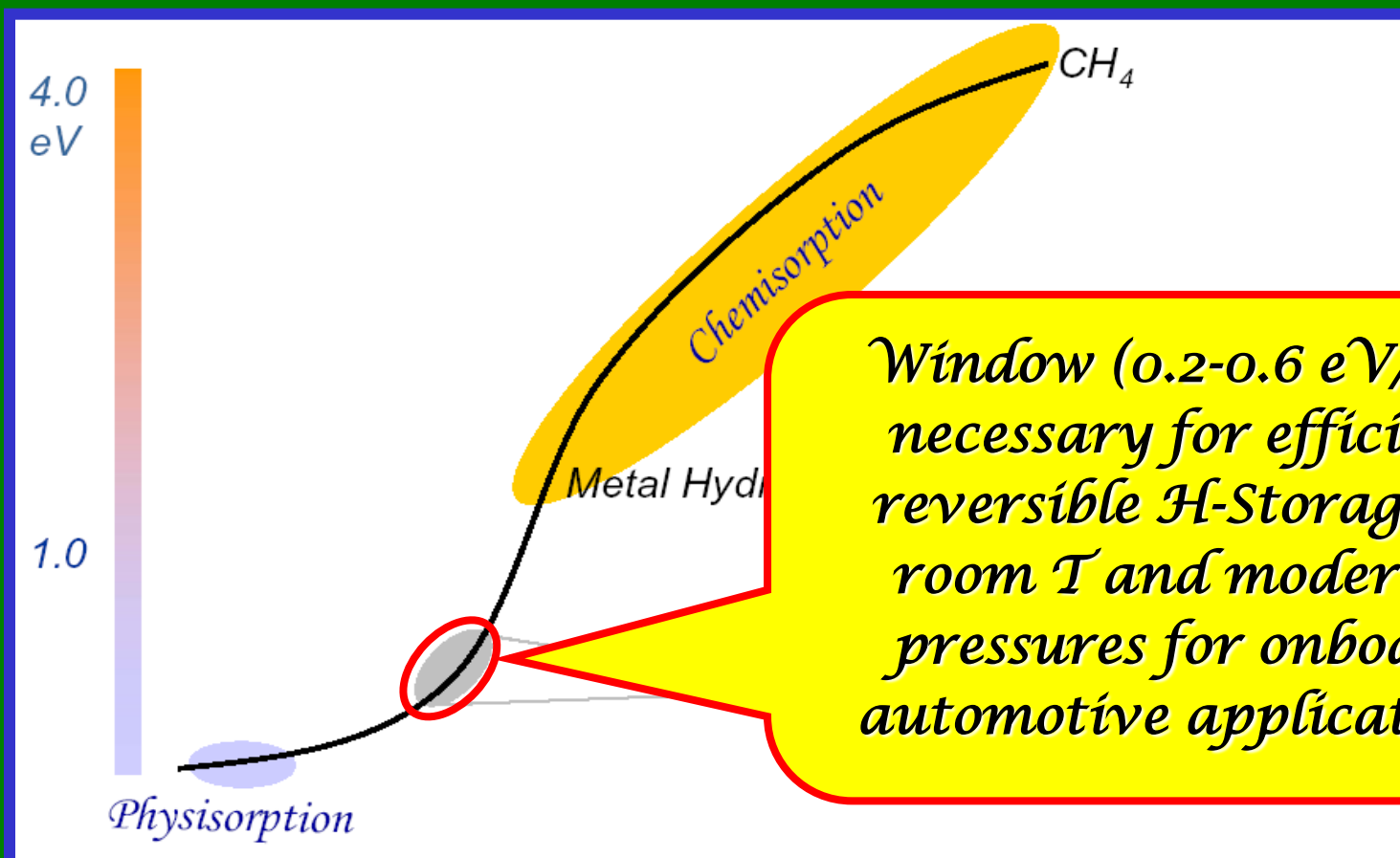
Liquid Crystals

Inorganic Chemistry

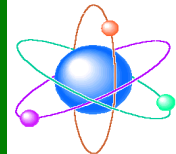
Nuclear Medicine (BNCT)



Hydrogen Storage



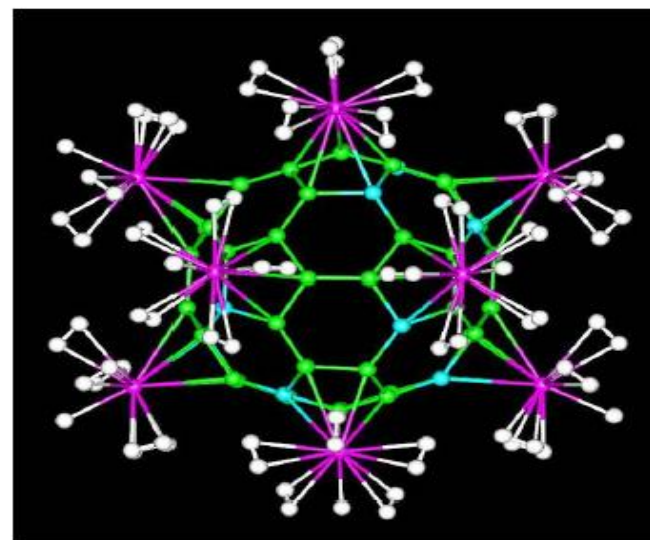
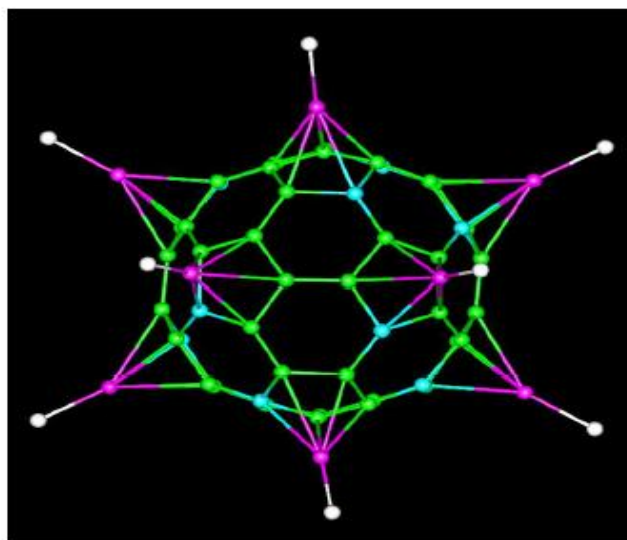
Materials needed for hydrogen storage are chemically non-dissociatively binding hydrogen molecules



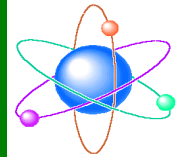
Hydrogen Storage I

H-Storage in Novel Organometallic Buckyballs

Zhao et al., PRL 94, 155504 (2005)



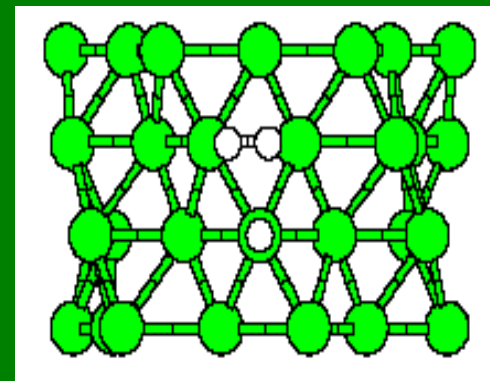
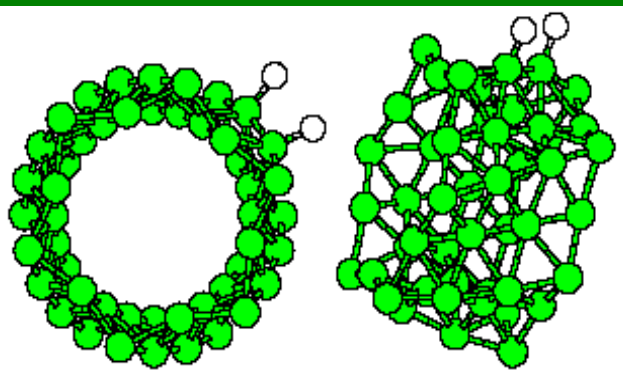
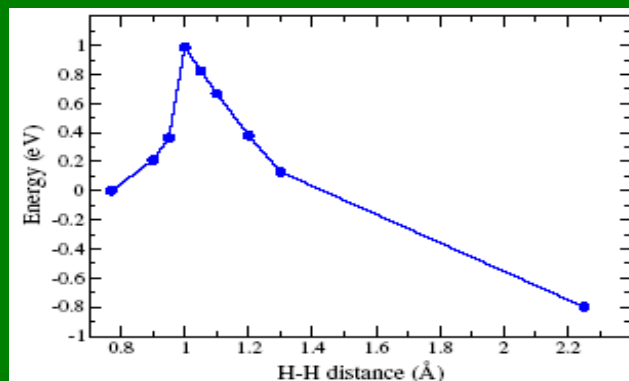
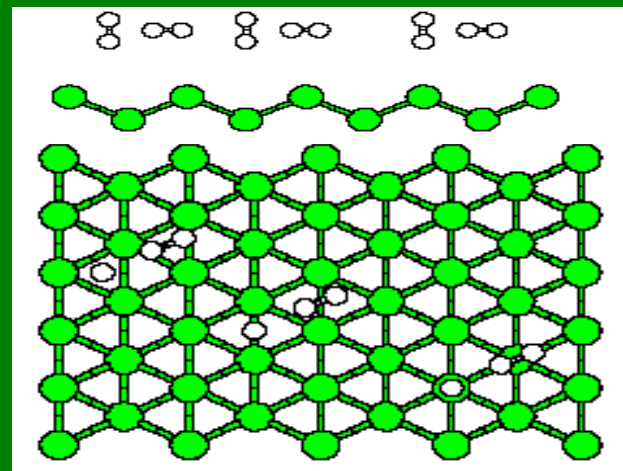
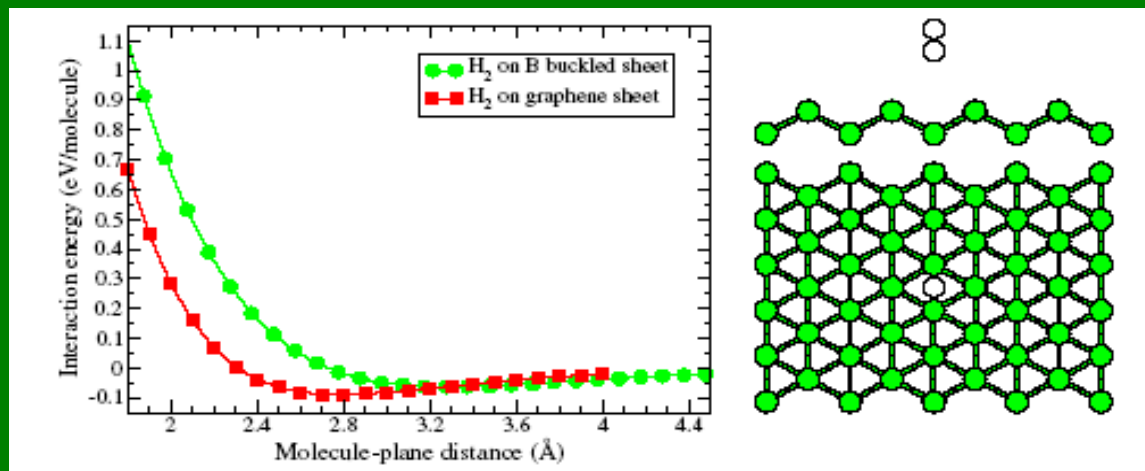
One more electron is transferred from each Sc atom to the corresponding pentagon, which enhances both the Sc-C46B12 binding and the hydrogen storage capacity.

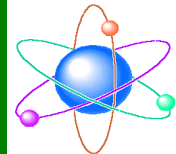


Hydrogen Storage II

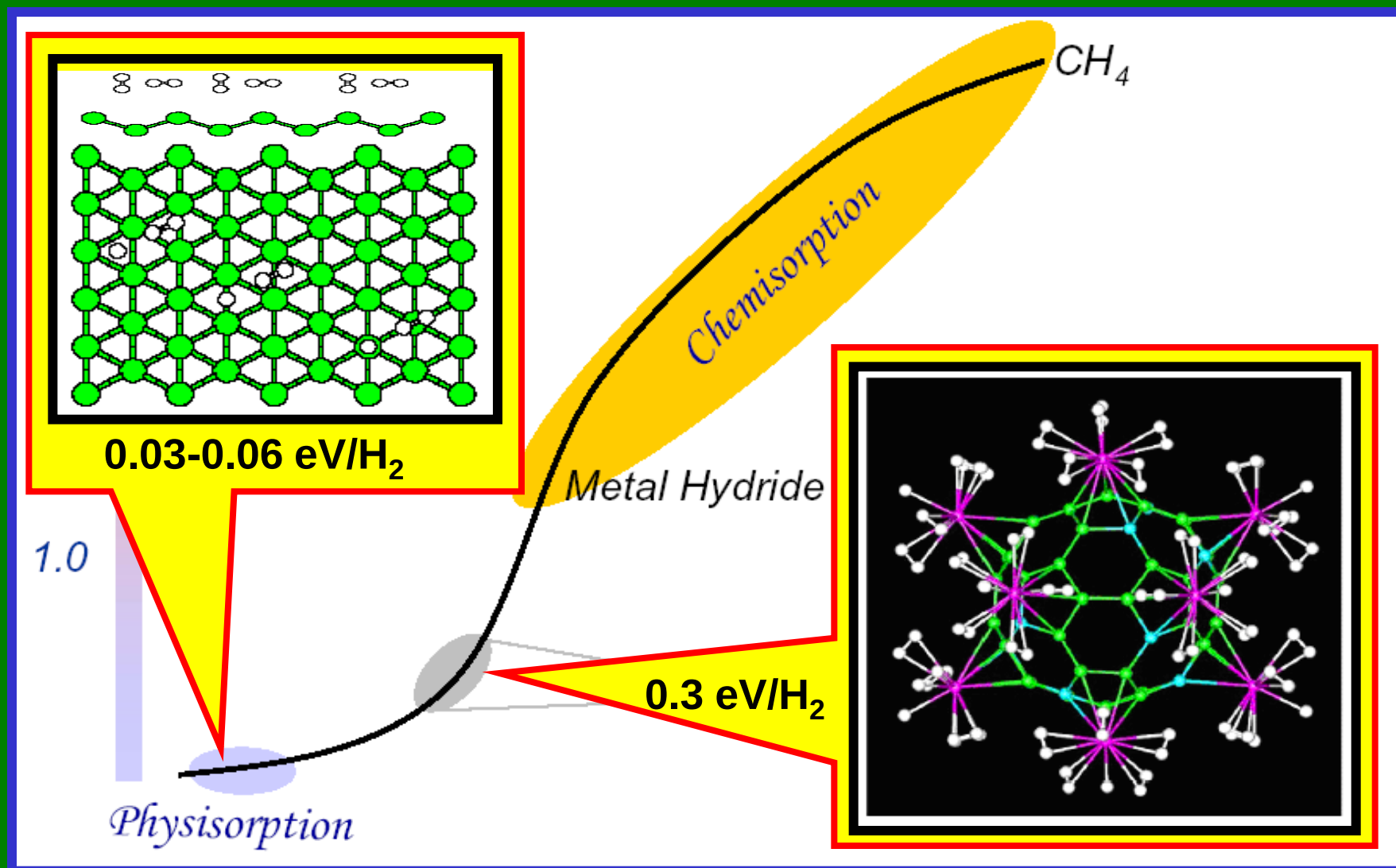
Physisorption on Boron Sheets and Nanotubes

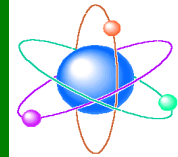
Cabria, Lopez and Alonso, Nanotechnology 17, 778 (2006)





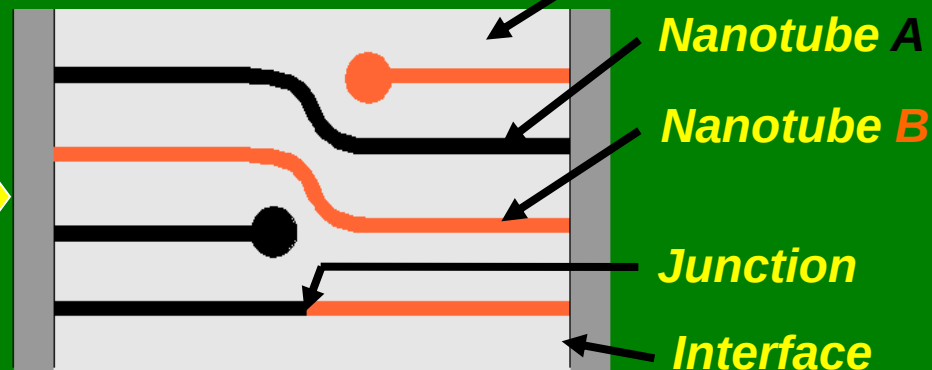
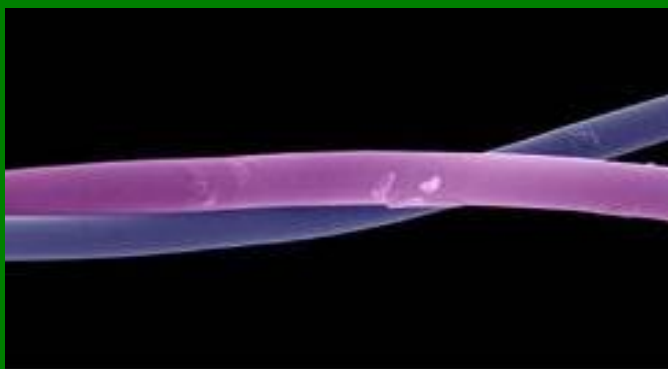
Hydrogen Storage



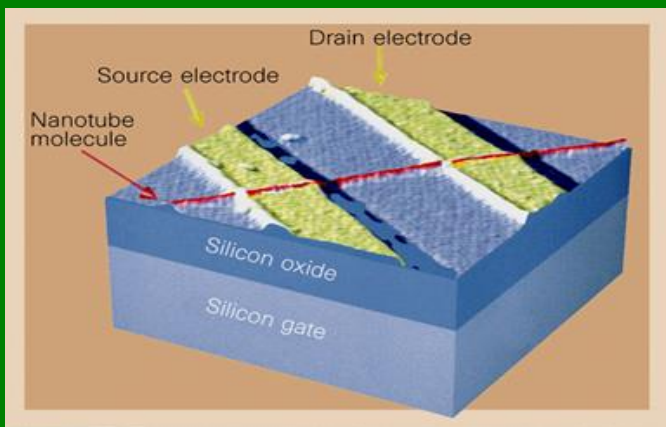


Nanotechnology

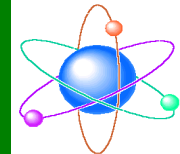
- Nanotubular Network



- Basic Layout for nanodevices

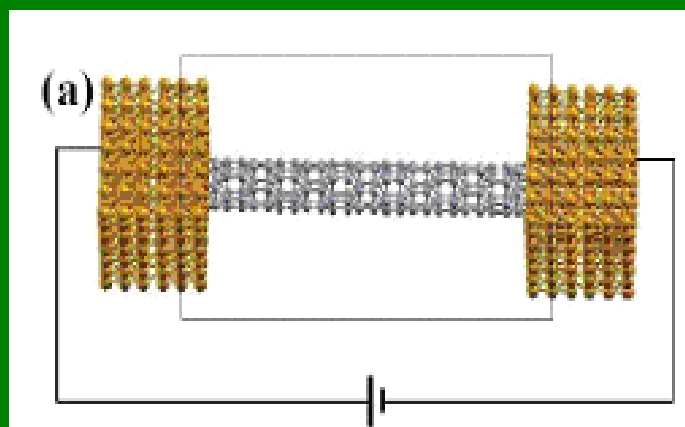


Nanowires, 5-10nm diameter



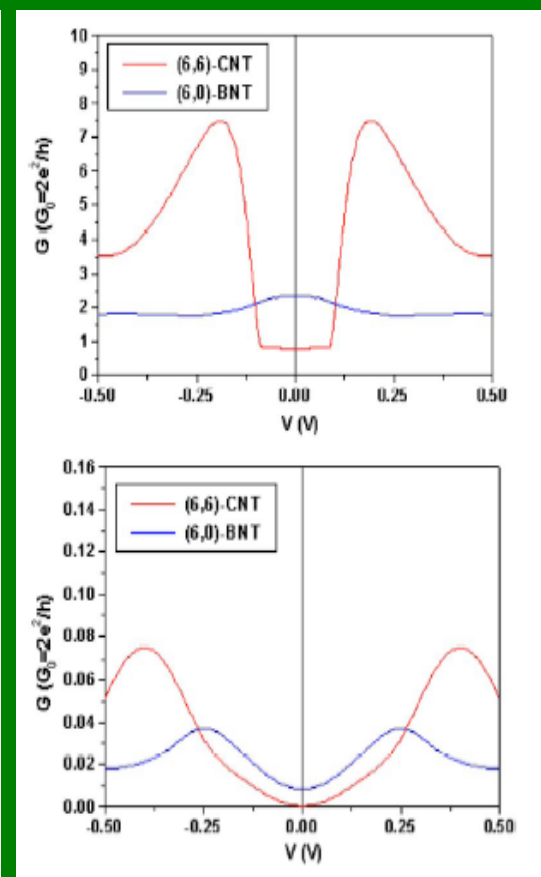
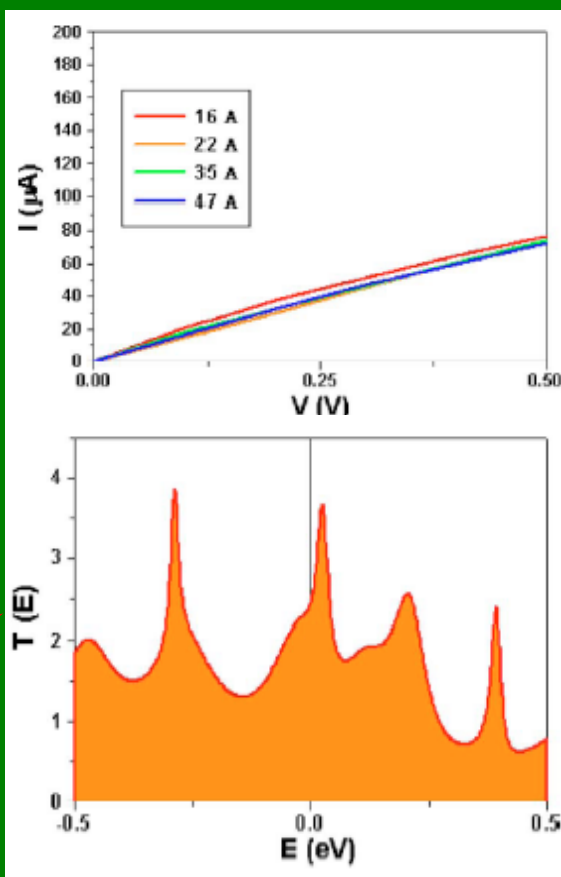
Electron Transport in Boron Nanotubes

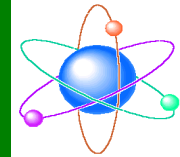
Lau & Pandey, et al., Appl. Phys. Lett., 88, 212111 (2006).



Schematic model of (6,0)
SWBNT between two
gold electrodes

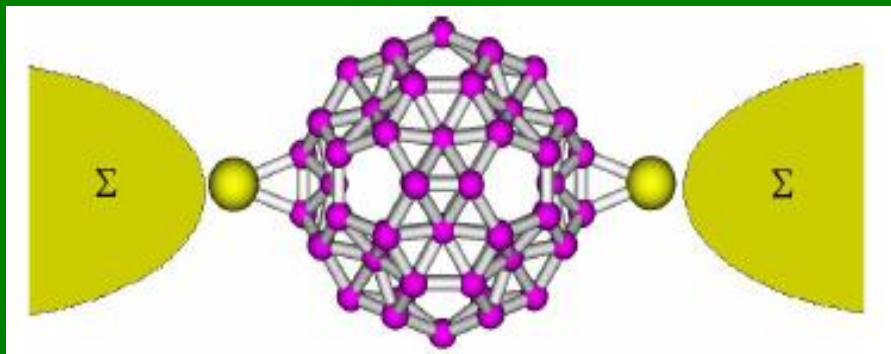
I-V characteristics and the
transmission spectra of the
system.



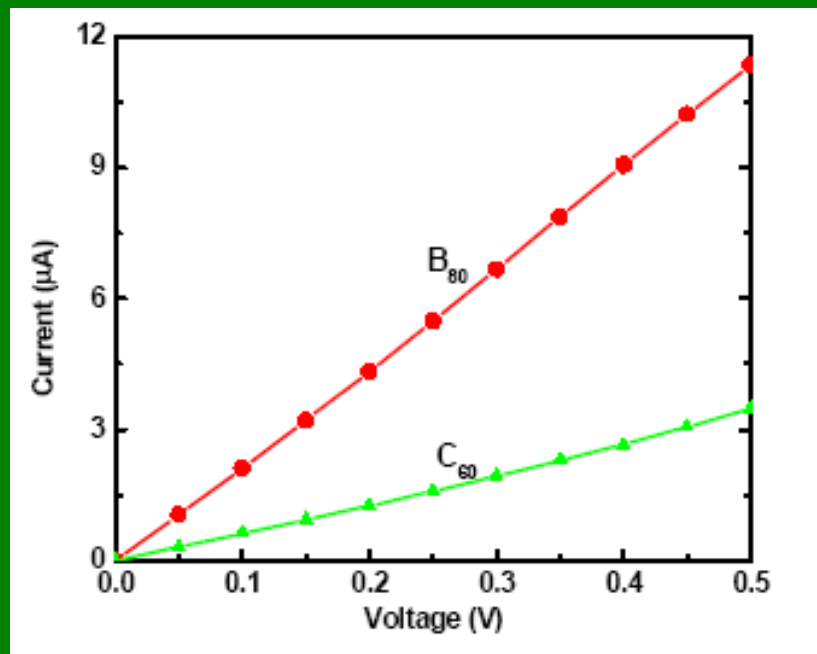
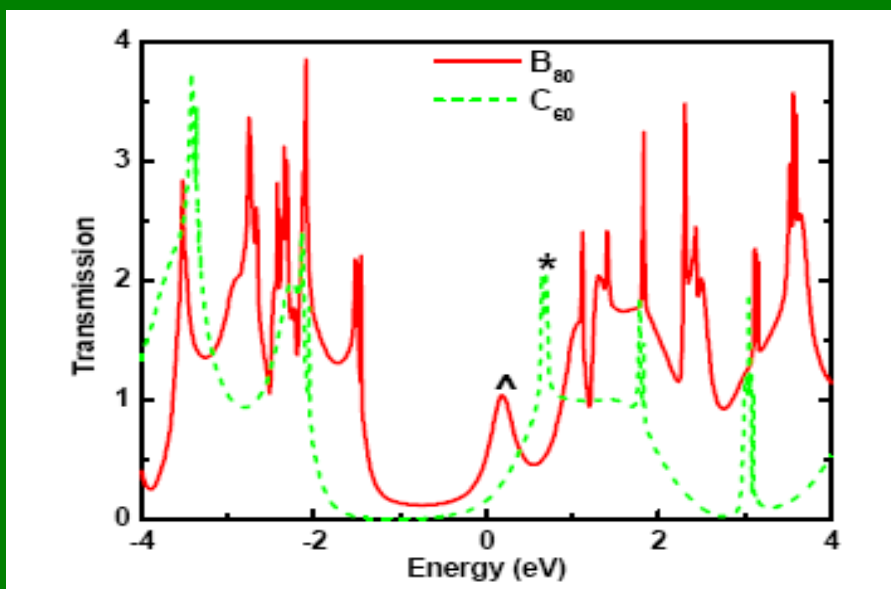


Elektron Transport in Boron Fullerenes

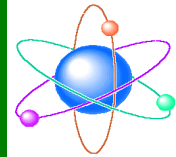
H. Hi, R. Pandey, and I. Boustani, IEEE (2008).



Schematic model of B_{80} Sphere
between two gold electrodes

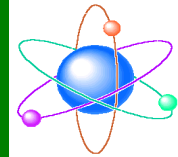


Current-voltage curves for B_{80}
and C_{60} molecular systems.



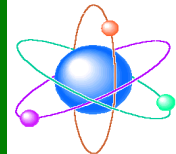
Conclusions

- We established a new fullerene-like researchfield called Boron Nanomaterials.
- Theory is able to predict nanostructures and the experimentally observed boron clusters and nanotubes are the best evidence.
- The planarity (aromaticitiy) of small boron clusters is *unique* between all atomic clusters known up to date.
- Boron Nanomaterials have (in opposite to carbon) potential applications in nanotechnology & medicine.



What is missing!

- **Theory** : Mech., Optical, Therm. and Electronic Properties, the Nature of $2e-3c$ Bonds, and the Aromaticity of the Most Boron Nanostructures, Simulation of Proteins@Nanotubes!
- Chemical Reaction of Boron Nanostructures with small molecules (H_2 , O_2 , HF, CO, CO_2 ...) $\rightarrow$ H-Storage, Sensoric !
- **Experiment** : Synthesis and Production of Boron Nanotubes & Fullerenes $\rightarrow$ New Synthesis-Methods are required
- Development the Chemistry of Boron Clusters & Fullerenes $\rightarrow$ Benefit of the Planarity and Aromaticity.
- Synthesis and Production of Boron Nanosheets & Thinfilms, $\rightarrow$ Does exist a Boron-Graphene or New Boron Phases!
- Can BNanoflakes&Sheets replace expensive $c-BN$ -Coating!
- Synthesis of Boron Nanomaterials for BNCT.
- Thermoelectric & Magnetic BNTs (Doping with TM & RE)



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P. Jensen

• *German Research Foundation DFG*

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A. Rubio

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P. Funke

• *Donostia Int. Physics Center*

P. Liebermann

• *Junta de Castilla y Leon*

Thank you for your attention